

# TPS549D22 1.5-V to 16-V $V_{IN}$ , 4.5-V to 22-V $V_{DD}$ , 40-A SWIFT™ Synchronous Step-Down Converter with Full Differential Sense and PMBus™

## 1 Features

- Input Voltage Range ( $PV_{IN}$ ): 1.5 V to 16 V
- Input Bias Voltage ( $V_{DD}$ ) Range: 4.5 V to 22 V
- Output Voltage Range: 0.6 V to 5.5 V
- Integrated, 2.9-m $\Omega$  and 1.2-m $\Omega$  Power MOSFETs With 40-A Continuous Output Current
- Voltage Reference 0.6 V to 1.2 V in 50-mV Steps Using VSEL Pin
- $\pm 0.5\%$ , 0.9- $V_{REF}$  Tolerance Range:  $-40^{\circ}\text{C}$  to  $+125^{\circ}\text{C}$  Junction Temperature
- True Differential Remote Sense Amplifier
- D-CAP3™ Control Loop
- Adaptive On-Time Control with 8 PMBus™ Frequency: 315 kHz, 425 kHz, 550 kHz, 650 kHz, 825 kHz, 900 kHz, 1.025 MHz, 1.125 MHz
- Temperature Compensated and Programmable Current Limit with  $R_{ILIM}$  and OC Clamp
- Choice of Hiccup or Latch-Off OVP or UVP
- VDD UVLO External Adjustment by Precision EN
- Prebias Start-up Support
- Eco-mode™ and FCCM Selectable
- Full Suite of Fault Protection and PGOOD
- Standard VOUT\_COMMAND and VOUT\_MARGIN (HIGH and LOW)
- Pin-Strapping and On-the-Fly Programming
- Fault Reporting and Warning
- NVM Backup for Selected Commands
- 1-MHz PMBus with PEC and SMB\_ALERT#
- Create a Custom Design Using the TPS549D22 With the [WEBENCH® Power Designer](#)

## 2 Applications

- Enterprise Storage, SSD, NAS
- Wireless and Wired Communication Infrastructure
- Industrial PCs, Automation, ATE, PLC, Video Surveillance
- Enterprise Server, Switches, Routers
- ASIC, SoC, FPGA, DSP Core, and I/O Rails

## 3 Description

The TPS549D22 device is a compact single buck converter with adaptive on-time, D-CAP3 mode control. It is designed for high accuracy, high efficiency, fast transient response, ease-of-use, low external component count and space-conscious power systems.

This device features full differential sense, TI integrated FETs with a high-side on-resistance of 2.9 m $\Omega$  and a low-side on-resistance of 1.2 m $\Omega$ . The device also features accurate 0.5%, 0.9-V reference with an ambient temperature range between  $-40^{\circ}\text{C}$  and  $+125^{\circ}\text{C}$ . Competitive features include: very low external component count, accurate load regulation and line regulation, auto-skip or FCCM mode operation, and internal soft-start control.

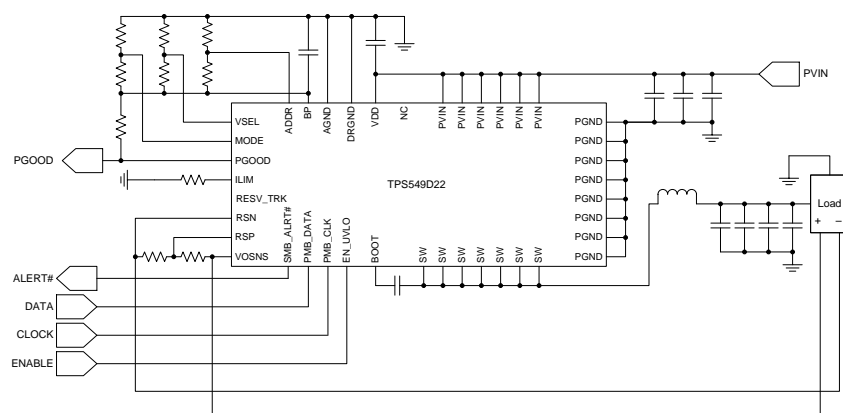
The TPS549D22 device is available in 7-mm  $\times$  5-mm, 40-pin, LQFN-CLIP (RVF) package (RoHs exempt).

### Device Information<sup>(1)</sup>

PART NUMBER	PACKAGE	BODY SIZE (NOM)
TPS549D22	LQFN-CLIP (40)	7.00 mm $\times$ 5.00 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

### Simplified Application



Copyright © 2016, Texas Instruments Incorporated



## Table of Contents

<b>1 Features</b> .....	<b>1</b>	<b>8 Application and Implementation</b> .....	<b>42</b>
<b>2 Applications</b> .....	<b>1</b>	8.1 Application Information.....	42
<b>3 Description</b> .....	<b>1</b>	8.2 Typical Application: TPS549D22 1.5-V to 16-V Input, 1-V Output, 40-A Converter .....	43
<b>4 Revision History</b> .....	<b>2</b>	<b>9 Power Supply Recommendations</b> .....	<b>54</b>
<b>5 Pin Configuration and Functions</b> .....	<b>3</b>	<b>10 Layout</b> .....	<b>54</b>
<b>6 Specifications</b> .....	<b>4</b>	10.1 Layout Guidelines .....	54
6.1 Absolute Maximum Ratings .....	4	10.2 Layout Example .....	55
6.2 ESD Ratings.....	4	<b>11 Device and Documentation Support</b> .....	<b>58</b>
6.3 Recommended Operating Conditions.....	4	11.1 Device Support .....	58
6.4 Thermal Information .....	5	11.2 Custom Design With WEBENCH® Tools .....	58
6.5 Electrical Characteristics.....	5	11.3 Receiving Notification of Documentation Updates .....	58
6.6 Typical Characteristics .....	9	11.4 Community Resources.....	58
<b>7 Detailed Description</b> .....	<b>13</b>	11.5 Trademarks .....	58
7.1 Overview .....	13	11.6 Electrostatic Discharge Caution.....	58
7.2 Functional Block Diagram .....	14	11.7 Glossary .....	59
7.3 Feature Description.....	14	<b>12 Mechanical, Packaging, and Orderable</b> <b>Information</b> .....	<b>59</b>
7.4 Device Functional Modes.....	18	12.1 Package Option Addendum .....	60
7.5 Programming.....	18		

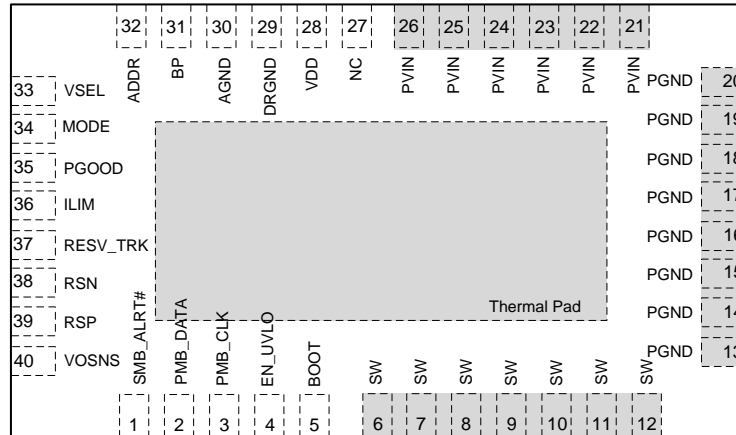
## 4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Original (August 2016) to Revision A	Page
• Changed package name to correct "LQFN-CLIP" .....	1
• add links for WEBENCH .....	1
• Added MIN and MAX values for VDD UVLO rising threshold.....	5
• Added MIN and MAX for all Soft Start settings and table notes 3 and 4 in <a href="#">Electrical Characteristics</a> .....	7
• Changed $V_{OUT} = 5\text{ V}$ to $V_{OUT} = 5.5\text{ V}$ for <a href="#">Figure 24</a> .....	15
• Added note 2 for "Allowable Mode Selection" table .....	20
• Added <a href="#">Application Workaround to Support 4-ms and 8-ms SS Settings</a> .....	20
• Added <a href="#">Figure 27</a> and <a href="#">Figure 28</a> .....	20
• Added "programmable" between "1-ms" and "delay" .....	22
• Changed 0, 1, 4 from "R/W" to "R" in ON_OFF CONFIG figure and table .....	28
• Deleted duplicative STATUS_BYTE table and figure.....	32
• Changed "286" to "2.86" in <a href="#">Minimum Output Capacitance to Ensure Stability</a> subsection .....	46
• Changed "1.6 $\mu\text{s}$ " to "1.538 $\mu\text{s}$ "; "150 ns" to "300 ns"; and "963 $\mu\text{F}$ " to "969 $\mu\text{F}$ " in <a href="#">Response to a Load Transient</a> .....	47

## 5 Pin Configuration and Functions

**RVF Package  
40-Pin LQFN-CLIP With Thermal Pad  
Top View**



### Pin Functions

PIN		I/O/P <sup>(1)</sup>	DESCRIPTION
NAME	NO.		
AGND	30	G	Ground pin for internal analog circuits.
BOOT	5	P	Supply rail for high-side gate driver (boot terminal). Connect boot capacitor from this pin to SW node. Internally connected to BP via bootstrap PMOS switch.
BP	31	O	LDO output
DRGND	29	P	Internal gate driver return.
EN_UVLO	4	I	Enable pin that can turn on the DC/DC switching converter. Use also to program the required PVIN UVLO when PVIN and VDD are connected together.
ADDR	32	I	Program device address and SKIP or FCCM mode.
ILIM	36	I/O	Program overcurrent limit by connecting a resistor to ground.
MODE	34	I	Mode selection pin. Select the control mode (DCAP3 or DCAP), and soft-start timing selection.
NC	27		No connect.
PGND	13, 14, 15, 16, 17, 18, 19, 20	P	Power ground of internal FETs.
PGOOD	35	O	Open drain power good status signal.
PMB_CLK	3	I	Clock input for the PMBus interface.
PMB_DATA	2	I/O	Data I/O for the PMBus interface.
PVIN	21, 22, 23, 24, 25, 26	P	Power supply input for integrated power MOSFET pair.
RSN	38	I	Inverting input of the differential remote sense amplifier.
RSP	39	I	Non-inverting input of the differential remote sense amplifier.
RESV_TRK	37	I	Do not connect.
SMB_ALRT#	1	O	Alert output for the PMBus interface.
SW	6, 7, 8, 9, 10, 11, 12	I/O	Output switching terminal of power converter. Connect the pins to the output inductor.
VDD	28	P	Controller power supply input.
VOSNS	40	I	Output voltage monitor input pin.
VSEL	33	I	Program the initial start-up and or reference voltage without feedback resistor dividers (from 0.6 V to 1.2 V in 50-mV increments).

(1) I = input, O = output, G = GND

## 6 Specifications

### 6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) <sup>(1)(2)</sup>

		MIN	MAX	UNIT
Input voltage	PVIN	−0.3	25	V
	VDD	−0.3	25	
	BOOT	−0.3	34	
	BOOT to SW	DC	7.7	
		< 10 ns	9.0	
	PMB_CLK, PMB_DATA	−0.3	6	
	EN_UVLO, VOSNS, MODE, ADDR, ILIM	−0.3	7.7	
	RSP, RESV_TRK, VSEL	−0.3	3.6	
	RSN	−0.3	0.3	
	PGND, AGND, DRGND	−0.3	0.3	
	SW	DC	25	
		< 10 ns	−5	
Output voltage	PGOOD, BP	−0.3	7.7	V
Output voltage	SMB_ALRT#, PMB_DATA	−0.3	6	V
Junction temperature, T <sub>J</sub>		−55	150	°C
Storage temperature, T <sub>stg</sub>		−55	150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values are with respect to the network ground terminal unless otherwise noted.

### 6.2 ESD Ratings

		VALUE	UNIT
V <sub>(ESD)</sub>	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>	±2000
		Charged-device model (CDM), per JEDEC specification JESD22-C101 <sup>(2)</sup>	±500

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

### 6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
Input voltage	PVIN	1.5	16	V
	VDD	4.5	22	
	BOOT	−0.1	24.5	
	BOOT to SW	DC	6.5	
		< 10 ns	7	
	PMB_CLK, PMB_DATA	−0.1	5.5	
	EN_UVLO, VOSNS, MODE, ADDR, ILIM	−0.1	5.5	
	RSP, RESV_TRK, VSEL	−0.1	3.3	
	RSN	−0.1	0.1	
	PGND, AGND, DRGND	−0.1	0.1	
	SW	DC	18	
		< 10 ns	−5	
Output voltage	PGOOD, BP	−0.1	7	V
Output voltage	SMB_ALRT#, PMB_DATA	−0.1	5.5	V
Junction temperature, T <sub>J</sub>		−40	125	°C



## 6.4 Thermal Information

THERMAL METRIC <sup>(1)</sup>		TPS549D22	UNIT
		RVF (LQFN-CLIP)	
		(40 PINS)	
R <sub>θJA</sub>	Junction-to-ambient thermal resistance	28.5	°C/W
R <sub>θJC(top)</sub>	Junction-to-case (top) thermal resistance	18.3	°C/W
R <sub>θJB</sub>	Junction-to-board thermal resistance	3.6	°C/W
ψ <sub>JT</sub>	Junction-to-top characterization parameter	0.96	°C/W
ψ <sub>JB</sub>	Junction-to-board characterization parameter	3.6	°C/W
R <sub>θJC(bot)</sub>	Junction-to-case (bottom) thermal resistance	0.6	°C/W

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

## 6.5 Electrical Characteristics

over operating free-air temperature range, V<sub>VDD</sub> = 12 V, V<sub>EN\_UVLO</sub> = 5 V (unless otherwise noted)

PARAMETER		TEST CONDITION	MIN	TYP	MAX	UNIT
<b>MOSFET ON-RESISTANCE (R<sub>DS(on)</sub>)</b>						
R <sub>DS(on)</sub>	High-side FET	(V <sub>BOOT</sub> – V <sub>SW</sub> ) = 5 V, I <sub>D</sub> = 25 A, T <sub>J</sub> = 25°C		2.9		mΩ
	Low-side FET	V <sub>VDD</sub> = 5 V, I <sub>D</sub> = 25 A, T <sub>J</sub> = 25°C		1.2		mΩ
<b>INPUT SUPPLY AND CURRENT</b>						
V <sub>VDD</sub>	VDD supply voltage	Nominal VDD voltage range	4.5		22	V
I <sub>VDD</sub>	VDD bias current	No load, power conversion enabled (no switching), T <sub>A</sub> = 25°C		2		mA
I <sub>VDDSTBY</sub>	VDD standby current	No load, power conversion disabled, T <sub>A</sub> = 25°C		700		μA
<b>UNDERVOLTAGE LOCKOUT</b>						
V <sub>VDD_UVLO</sub>	VDD UVLO rising threshold		4.23	4.25	4.34	V
V <sub>VDD_UVLO(HYS)</sub>	VDD UVLO hysteresis			0.2		V
V <sub>EN_ON_TH</sub>	EN_UVLO on threshold		1.45	1.6	1.75	V
V <sub>EN_HYS</sub>	EN_UVLO hysteresis		270	300	340	mV
I <sub>EN_LKG</sub>	EN_UVLO input leakage current	V <sub>EN_UVLO</sub> = 5 V	–1	0	1	μA
<b>INTERNAL REFERENCE VOLTAGE AND RANGE</b>						
V <sub>INTREF</sub>	Internal REF voltage			900.4		mV
V <sub>INTREFTOL</sub>	Internal REF voltage tolerance	–40°C ≤ T <sub>J</sub> ≤ 125°C	–0.5%		0.5%	
V <sub>INTREF</sub>	Internal REF voltage range		0.6		1.2	V
<b>OUTPUT VOLTAGE</b>						
V <sub>IOS_LPCMP</sub>	Loop comparator input offset voltage <sup>(1)</sup>		–2.5		2.5	mV
I <sub>RSP</sub>	RSP input current	V <sub>RSP</sub> = 600 mV	–1		1	μA
I <sub>VO(dis)</sub>	VO discharge current	V <sub>VO</sub> = 0.5 V, power conversion disabled	8	12		mA
<b>DIFFERENTIAL REMOTE SENSE AMPLIFIER</b>						
f <sub>UGBW</sub>	Unity gain bandwidth <sup>(1)</sup>		5	7		MHz
A <sub>0</sub>	Open loop gain <sup>(1)</sup>		75			dB
SR	Slew rate <sup>(1)</sup>			±4.7		V/μsec
V <sub>IRNG</sub>	Input range <sup>(1)</sup>		–0.2		1.8	V
V <sub>OFFSET</sub>	Input offset voltage <sup>(1)</sup>		–3.5		3.5	mV
<b>INTERNAL BOOT STRAP SWITCH</b>						
V <sub>F</sub>	Forward voltage	V <sub>BP-BOOT</sub> , I <sub>F</sub> = 10 mA, T <sub>A</sub> = 25°C		0.1	0.2	V
I <sub>BOOT</sub>	VBST leakage current	V <sub>BOOT</sub> = 30 V, V <sub>SW</sub> = 25 V, T <sub>A</sub> = 25°C		0.01	1.5	μA

(1) Specified by design. Not production tested.

## Electrical Characteristics (continued)

over operating free-air temperature range,  $V_{DD} = 12\text{ V}$ ,  $V_{EN\_UVLO} = 5\text{ V}$  (unless otherwise noted)

PARAMETER	TEST CONDITION	MIN	TYP	MAX	UNIT
<b>SWITCHING FREQUENCY</b>					
$f_{SW}$ VO switching frequency <sup>(2)</sup>	$V_{IN} = 12\text{ V}$ , $V_{VO} = 1\text{ V}$ , $T_A = 25^\circ\text{C}$	275	315	350	kHz
		380	425	475	
		490	550	615	
		585	650	740	
		740	825	930	
		790	900	995	
		920	1025	1160	
		950	1125	1250	
$t_{ON(min)}$ Minimum on time <sup>(1)</sup>			60		ns
$t_{OFF(min)}$ Minimum off time <sup>(1)</sup>	DRVH falling to rising			300	ns
<b>MODE, VSEL, ADDR DETECTION</b>					
$V_{DETECT\_TH}$ MODE, VSEL, and ADDR detection voltage	$V_{BP} = 2.93\text{ V}$ , $R_{HIGH} = 100\text{ k}\Omega$	Open	$V_{BP}$		V
		$R_{LOW} = 187\text{ k}\Omega$	1.9091		
		$R_{LOW} = 165\text{ k}\Omega$	1.8243		
		$R_{LOW} = 147\text{ k}\Omega$	1.7438		
		$R_{LOW} = 133\text{ k}\Omega$	1.6725		
		$R_{LOW} = 121\text{ k}\Omega$	1.6042		
		$R_{LOW} = 110\text{ k}\Omega$	1.5348		
		$R_{LOW} = 100\text{ k}\Omega$	1.465		
		$R_{LOW} = 90.9\text{ k}\Omega$	1.3952		
		$R_{LOW} = 82.5\text{ k}\Omega$	1.3245		
		$R_{LOW} = 75\text{ k}\Omega$	1.2557		
		$R_{LOW} = 68.1\text{ k}\Omega$	1.187		
		$R_{LOW} = 60.4\text{ k}\Omega$	1.1033		
		$R_{LOW} = 53.6\text{ k}\Omega$	1.0224		
		$R_{LOW} = 47.5\text{ k}\Omega$	0.9436		
		$R_{LOW} = 42.2\text{ k}\Omega$	0.8695		
		$R_{LOW} = 37.4\text{ k}\Omega$	0.7975		
		$R_{LOW} = 33.2\text{ k}\Omega$	0.7303		
		$R_{LOW} = 29.4\text{ k}\Omega$	0.6657		
		$R_{LOW} = 25.5\text{ k}\Omega$	0.5953		
		$R_{LOW} = 22.1\text{ k}\Omega$	0.5303		
		$R_{LOW} = 19.1\text{ k}\Omega$	0.4699		
		$R_{LOW} = 16.5\text{ k}\Omega$	0.415		
		$R_{LOW} = 14.3\text{ k}\Omega$	0.3666		
		$R_{LOW} = 12.1\text{ k}\Omega$	0.3163		
		$R_{LOW} = 10\text{ k}\Omega$	0.2664		
		$R_{LOW} = 7.87\text{ k}\Omega$	0.2138		
		$R_{LOW} = 6.19\text{ k}\Omega$	0.1708		
		$R_{LOW} = 4.64\text{ k}\Omega$	0.1299		
		$R_{LOW} = 3.16\text{ k}\Omega$	0.0898		
		$R_{LOW} = 1.78\text{ k}\Omega$	0.0512		
		$R_{LOW} = 0\text{ }\Omega$	GND		

(2) Correlated with close loop EVM measurement at load current of 30 A.

## Electrical Characteristics (continued)

over operating free-air temperature range,  $V_{DD} = 12\text{ V}$ ,  $V_{EN\_UVLO} = 5\text{ V}$  (unless otherwise noted)

PARAMETER		TEST CONDITION	MIN	TYP	MAX	UNIT		
SOFT START								
t <sub>SS</sub>	Soft-start time	V <sub>OUT</sub> rising from 0 V to 95% of final set point, R <sub>MODE_HIGH</sub> = 100 kΩ	R <sub>MODE_LOW</sub> = 60.4 kΩ	7	8 <sup>(3)</sup>	ms		
			R <sub>MODE_LOW</sub> = 53.6 kΩ	3.6	4 <sup>(4)</sup>			
			R <sub>MODE_LOW</sub> = 47.5 kΩ	1.6	2			
			R <sub>MODE_LOW</sub> = 42.2 kΩ	0.8	1			
POWER-ON DELAY								
t <sub>PODLY</sub>	Power-on delay time	Delay from enable to switching POD[2:0] = 000	256			μs		
		Delay from enable to switching POD[2:0] = 001	512					
		Delay from enable to switching POD[2:0] = 010	1.024			ms		
		Delay from enable to switching POD[2:0] = 011	2.048					
		Delay from enable to switching POD[2:0] = 100	4.096					
		Delay from enable to switching POD[2:0] = 101	8.192					
		Delay from enable to switching POD[2:0] = 110	16.384					
		Delay from enable to switching POD[2:0] = 111	32.768					
PGOOD COMPARATOR								
V <sub>PGTH</sub>	PGOOD threshold	PGOOD in from higher	105	108	111	%V <sub>REF</sub>		
		PGOOD in from lower	89	92	95			
		PGOOD out to higher	120					
		PGOOD out to lower	68					
I <sub>PG</sub>	PGOOD sink current	V <sub>PGOOD</sub> = 0.5 V	6.9			mA		
t <sub>PGDLY</sub>	PGOOD delay time	Delay for PGOOD going in, PGD[2:0] = 000	256			μs		
		Delay for PGOOD going in, PGD[2:0] = 001	512					
		Delay for PGOOD going in, PGD[2:0] = 010	1.024			ms		
		Delay for PGOOD going in, PGD[2:0] = 011	2.048					
		Delay for PGOOD going in, PGD[2:0] = 100	4.096					
		Delay for PGOOD going in, PGD[2:0] = 101	8.192					
		Delay for PGOOD going in, PGD[2:0] = 110	16.384					
		Delay for PGOOD going in, PGD[2:0] = 111	131					
I <sub>PGLK</sub>	PGOOD leakage current	V <sub>PGOOD</sub> = 5 V	–1			0	1	μA
CURRENT DETECTION								
V <sub>ILM</sub>	V <sub>ILIM</sub> voltage range	On-resistance (R <sub>DS(on)</sub> ) sensing	0.1			1.2	V	
I <sub>OCL_VA</sub>	Valley current limit threshold	R <sub>LIM</sub> = 130 kΩ	40			A		
		OC tolerance	±10% <sup>(5)</sup>					
		R <sub>LIM</sub> = 97.6 kΩ	30			A		
		OC tolerance	±15% <sup>(5)</sup>					
		R <sub>LIM</sub> = 64.9 kΩ	20			A		
		OC tolerance	±20%					
I <sub>OCL_VA_N</sub>	Negative valley current limit threshold	R <sub>LIM</sub> = 130 kΩ	–40			A		
		R <sub>LIM</sub> = 97.6 kΩ	–30					
		R <sub>LIM</sub> = 64.9 kΩ	–20					
I <sub>CLMP_LO</sub>	Clamp current at V <sub>LIM</sub> clamp at lowest	V <sub>ILIM_CLMP</sub> = 0.1 V, T <sub>A</sub> = 25°C	6.25			A		
I <sub>CLMP_HI</sub>	Clamp current at V <sub>LIM</sub> clamp at highest	V <sub>ILIM_CLMP</sub> = 1.2 V, T <sub>A</sub> = 25°C	75			A		
V <sub>ZC</sub>	Zero cross detection offset		0			mV		

(3) In order to use the 8-ms SS setting, follow the steps outlined in *Application Workaround to Support 4-ms and 8-ms SS Settings*.

(4) In order to use the 4-ms SS setting, follow the steps outlined in *Application Workaround to Support 4-ms and 8-ms SS Settings*.

(5) Calculated from 20-A test data. Not production tested.

## Electrical Characteristics (continued)

 over operating free-air temperature range,  $V_{DD} = 12\text{ V}$ ,  $V_{EN\_UVLO} = 5\text{ V}$  (unless otherwise noted)

PARAMETER		TEST CONDITION	MIN	TYP	MAX	UNIT
PROTECTIONS AND OOB						
V <sub>BPUVLO</sub>	BP UVLO threshold voltage	Wake-up	3.32			V
		Shutdown	3.11			
V <sub>OVP</sub>	OVP threshold voltage	OVP detect voltage	117%	120%	123%	V <sub>REF</sub>
t <sub>OVPDLY</sub>	OVP response time	100-mV over drive	1			μs
V <sub>UVP</sub>	UVP threshold voltage	UVP detect voltage	65%	68%	71%	V <sub>REF</sub>
t <sub>UVPDLY</sub>	UVP delay filter delay time		1			ms
V <sub>OOB</sub>	OOB threshold voltage		8%			V <sub>REF</sub>
t <sub>HICDLY</sub>	Hiccup blanking time	t <sub>SS</sub> = 1 ms	16			ms
		t <sub>SS</sub> = 2 ms	24			ms
		t <sub>SS</sub> = 4 ms	38			ms
		t <sub>SS</sub> = 8 ms	67			ms
BP VOLTAGE						
V <sub>BP</sub>	BP LDO output voltage	V <sub>IN</sub> = 12 V, 0 A ≤ I <sub>LOAD</sub> ≤ 10 mA,	5.07			V
V <sub>BPDO</sub>	BP LDO dropout voltage	V <sub>IN</sub> = 4.5 V, I <sub>LOAD</sub> = 30 mA, T <sub>A</sub> = 25°C	365			mV
I <sub>BPMAX</sub>	BP LDO overcurrent limit	V <sub>IN</sub> = 12 V, T <sub>A</sub> = 25°C	100			mA
PMB_CLK and PMB_DATA INPUT BUFFER LOGIC THRESHOLDS						
V <sub>IL-PMBUS</sub>	PMB_CLK and PMB_DATA low-level input voltage <sup>(1)</sup>		0.8			V
V <sub>IH-PMBUS</sub>	PMB_CLK and PMB_DATA high-level input voltage <sup>(1)</sup>		1.35			V
V <sub>HY-PMBUS</sub>	PMB_CLK and PMB_DATA hysteresis voltage <sup>(1)</sup>		150			mV
PMB_CLK and SMB_ALERT OUTPUT PULLDOWN						
V <sub>OL-PMBUS</sub>	PMB_DATA and SMB_ALERT low-level output voltage <sup>(1)</sup>	I <sub>SINK</sub> = 20 mA	0.4			V
THERMAL SHUTDOWN						
T <sub>SDN</sub>	Built-In thermal shutdown threshold <sup>(1)</sup>	Shutdown temperature	155	165		°C
		Hysteresis	30			

## 6.6 Typical Characteristics

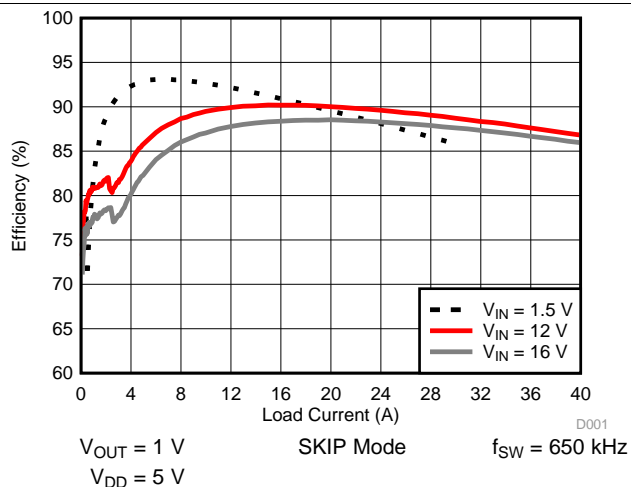


Figure 1. Efficiency vs Output Current

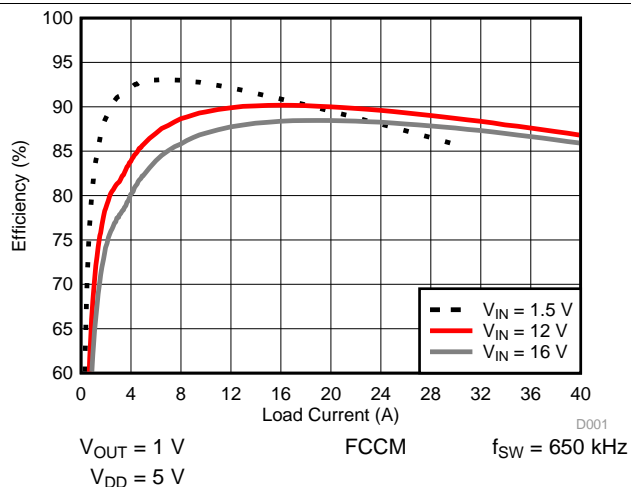


Figure 2. Efficiency vs Output Current

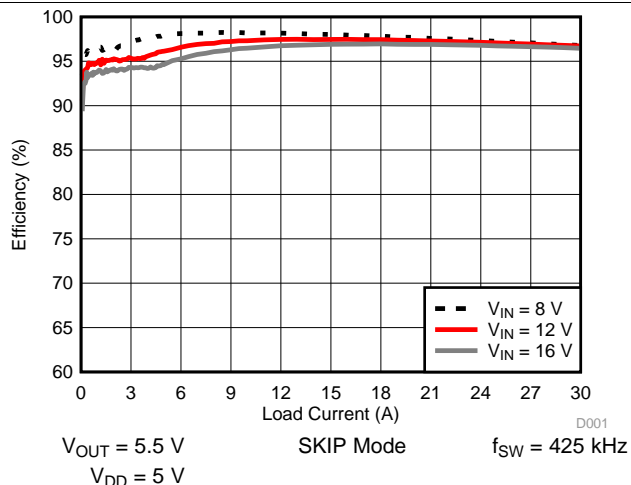


Figure 3. Efficiency vs Output Current

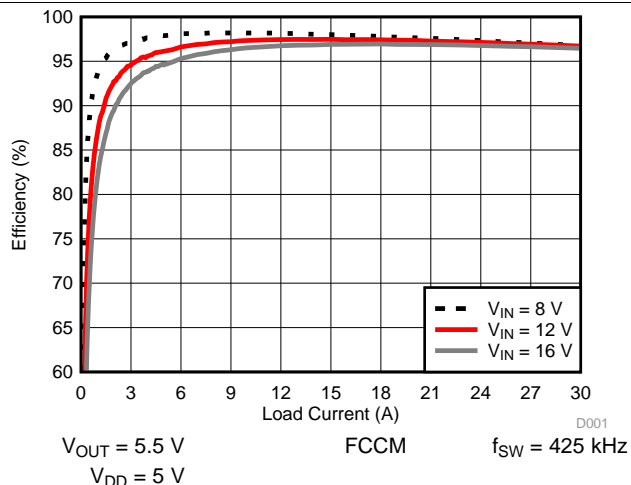


Figure 4. Efficiency vs Output Current

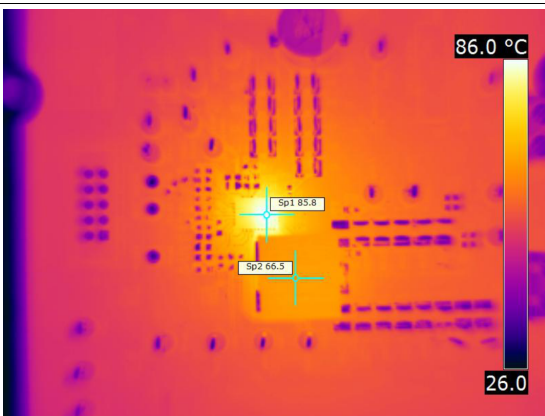


Figure 5. Thermal Image

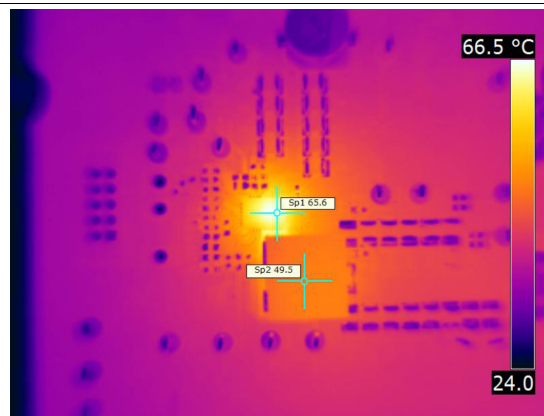
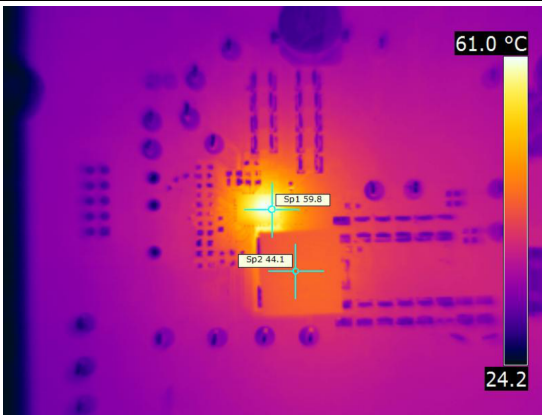


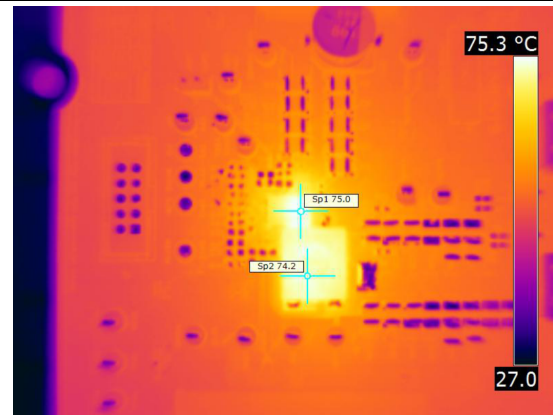
Figure 6. Thermal Image

## Typical Characteristics (continued)



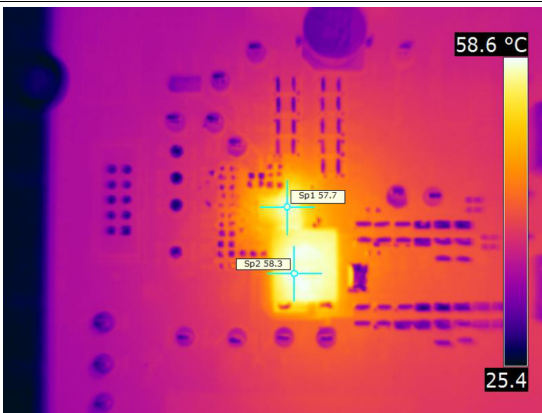
$V_{IN} = 12\text{ V}$   $f_{SW} = 650\text{ kHz}$   $I_{OUT} = 40\text{ A}$   
 $V_{OUT} = 1\text{ V}$  Airflow = 400 LFM

**Figure 7. Thermal Image**



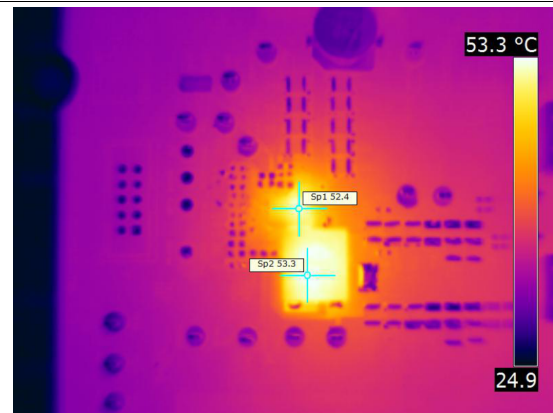
$V_{IN} = 12\text{ V}$   $f_{SW} = 425\text{ kHz}$   $I_{OUT} = 30\text{ A}$   
 $V_{OUT} = 5.5\text{ V}$  Natural convection

**Figure 8. Thermal Image**



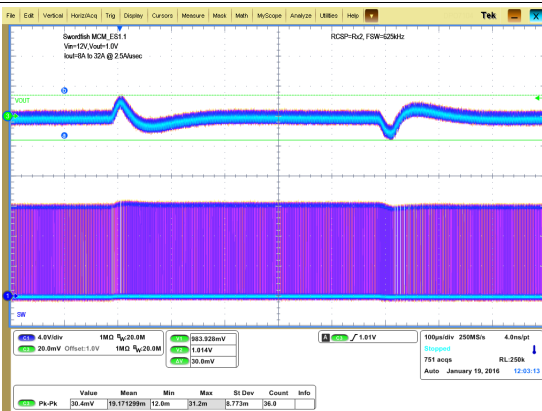
$V_{IN} = 12\text{ V}$   $f_{SW} = 425\text{ kHz}$   $I_{OUT} = 30\text{ A}$   
 $V_{OUT} = 5.5\text{ V}$  Airflow = 200 LFM

**Figure 9. Thermal Image**



$V_{IN} = 12\text{ V}$   $f_{SW} = 425\text{ kHz}$   $I_{OUT} = 30\text{ A}$   
 $V_{OUT} = 5.5\text{ V}$  Airflow = 400 LFM

**Figure 10. Thermal Image**



$V_{OUT} = 1\text{ V}$   $V_{IN} = 12\text{ V}$   
 $I_{OUT}$  from 8 A to 32 A 2.5 A/μs

**Figure 11. Transient Response Peak-to-Peak**

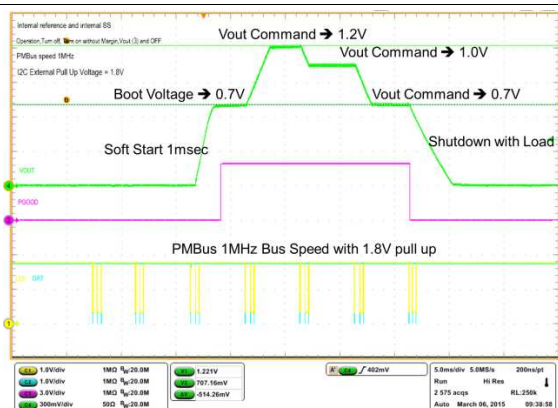


$V_{OUT} = 5.5\text{ V}$   $V_{IN} = 12\text{ V}$   
 $I_{OUT}$  from 6 A to 24 A 2.5 A/μs

**Figure 12. Transient Response Peak-to-Peak**



## Typical Characteristics (continued)



**Figure 13. PMBus 1-MHz Bus Speed with 1.8-V Pullup**



- 1 – Operation only
- 2 – Turn off
- 3 – Turn on without Margin
- 4 – Vout Command up to 1.2 V
- 5 – Vout Command down to 0.6 V
- 6 – Turn off

**Figure 14. 6 Sequenced Events – I2C Write**



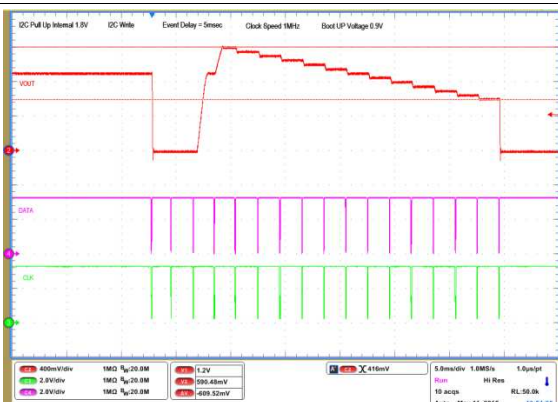
- 1 – Operation only
- 2 – Turn off
- 3 – Turn on without Margin
- 4 – Vout Command up to 1.2 V
- 5 – Vout Command down to 0.6 V
- 6 – Turn off

**Figure 15. 6 Sequenced Events – I2C Write/Read**



- 1 – Operation only
- 2 – Turn off
- 3 – Turn on without Margin
- 4 – Vout Command up to 1.2 V
- 5 – Vout Command down to 0.6 V
- 6 – Turn off

**Figure 16. 6 Sequenced Events – I2C Write/Read with PEC**



- 1 – Operation only
- 2 – Turn off
- 3 – Turn on without Margin
- 4 – 16 Vout Command up to 1.2 V,  
50 mV per step down to 0.6 V
- 17 – Turn off

**Figure 17. 17 Sequenced Events – I2C Write**



- 1 – Operation only
- 2 – Turn off
- 3 – Turn on without Margin
- 4 – 16 Vout Command up to 1.2 V,  
50 mV per step down to 0.6 V
- 17 – Turn off

**Figure 18. 17 Sequenced Events – I2C Write/Read**

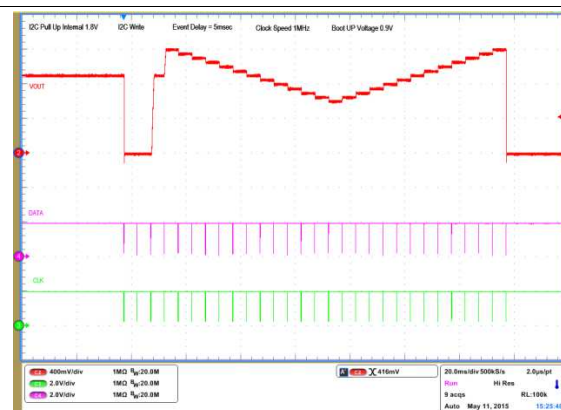


## Typical Characteristics (continued)



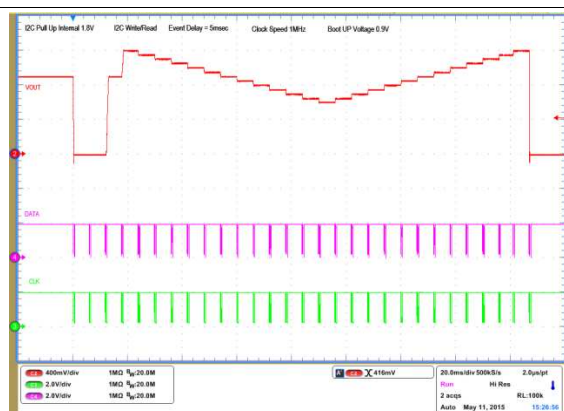
- 1 – Operation only
- 2 – Turn off
- 3 – Turn on without Margin
- 4 – 16 Vout Command up to 1.2 V, 50 mV per step down to 0.6 V
- 17 – Turn off

**Figure 19. 17 Sequenced Events – I2C Write/Read with PEC**



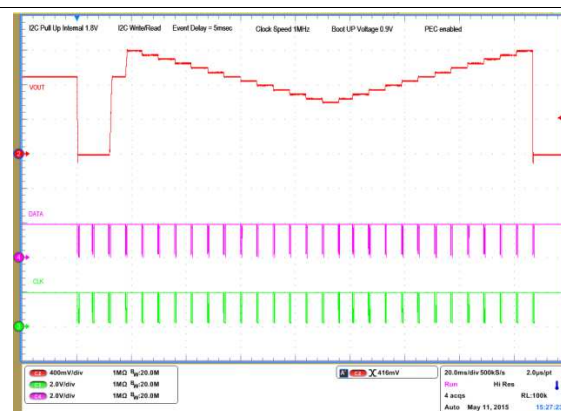
- 1 – Operation only
- 2 – Turn off
- 3 – Turn on without Margin
- 4 – 16 Vout Command up to 1.2 V, 50 mV per step down to 0.6 V
- 17 – 28 Vout Command from 0.6 V to 1.2 V, 50 mV per step
- 29 – Turn off

**Figure 20. 29 Sequenced Events – I2C Write**



- 1 – Operation only
- 2 – Turn off
- 3 – Turn on without Margin
- 4 – 16 Vout Command up to 1.2 V, 50 mV per step down to 0.6 V
- 17 – 28 Vout Command from 0.6 V to 1.2 V, 50 mV per step
- 29 – Turn off

**Figure 21. 29 Sequenced Events – I2C Write/Read**



- 1 – Operation only
- 2 – Turn off
- 3 – Turn on without Margin
- 4 – 16 Vout Command up to 1.2 V, 50 mV per step down to 0.6 V
- 17 – 28 Vout Command from 0.6 V to 1.2 V, 50 mV per step
- 29 – Turn off

**Figure 22. 29 Sequenced Events – I2C Write/Read with PEC**

## 7 Detailed Description

### 7.1 Overview

TPS549D22 device is a high-efficiency, single channel, FET-integrated, synchronous buck converter. It is suitable for point-of-load applications with 40 A or lower output current in storage, telecom, and similar digital applications. The device features proprietary D-CAP3 mode control combined with adaptive on-time architecture. This combination is ideal for building modern high/low duty ratio, ultra-fast load step response DC-DC converters.

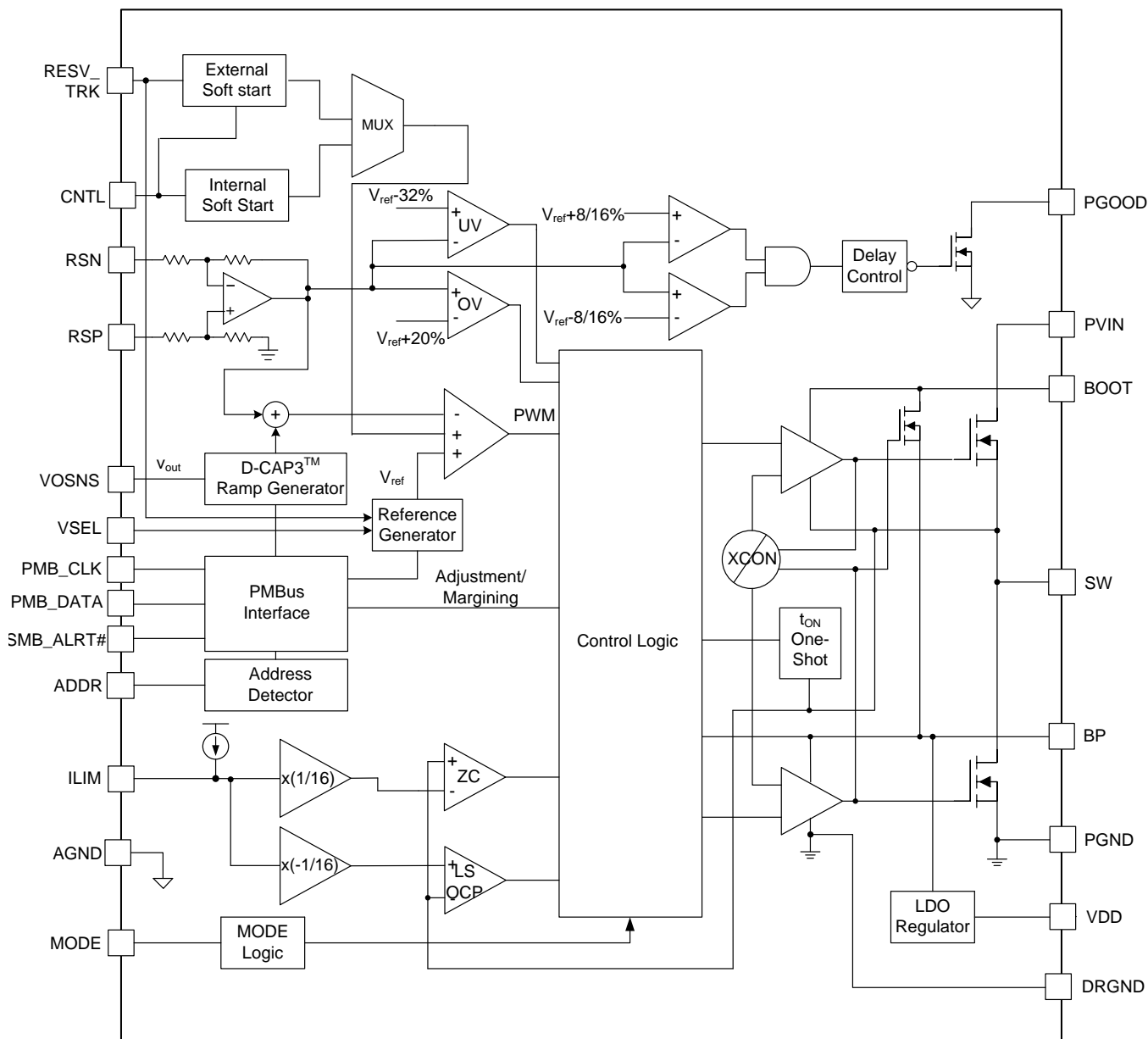
TPS549D22 device has integrated MOSFETs rated at 40-A TDC.

The converter input voltage range is from 1.5 V up to 16 V, and the VDD input voltage range is from 4.5 V to 22 V. The output voltage ranges from 0.6 V to 5.5 V.

Stable operation with all ceramic output capacitors is supported, since the D-CAP3 mode uses emulated current information to control the modulation. An advantage of this control scheme is that it does not require phase compensation network outside which makes it easy to use and also enables low external component count. Adaptive on-time control tracks the preset switching frequency over a wide range of input and output voltage while increasing switching frequency as needed during load-step transient.

The default preset switching frequency for this device is 650 kHz. Switching frequency is also programmable from 8 preset values via PMBus interface. TPS549D22 supports digital communication via PMBus using standard interfacing pins, PMB\_CLK, PMB\_DATA and SMB\_ALRT#. The detailed PMBus features, capabilities and command sets of the TPS549D22 can be found in the [PMBus Programming](#) section.

## 7.2 Functional Block Diagram



Copyright © 2016, Texas Instruments Incorporated

## 7.3 Feature Description

### 7.3.1 40-A FET

The TPS549D22 device is a high-performance, integrated FET converter supporting current rating up to 40 A thermally. It integrates two N-channel NexFET™ power MOSFETs, enabling high power density and small PCB layout area. The drain-to-source breakdown voltage for these FETs is 25 V DC and 27 V transient for 10 ns. Avalanche breakdown occurs if the absolute maximum voltage rating exceeds 27 V. In order to limit the switch node ringing of the device, it is recommended to add a R-C snubber from the SW node to the PGND pins. Refer to the [Layout Guidelines](#) section for the detailed recommendations.

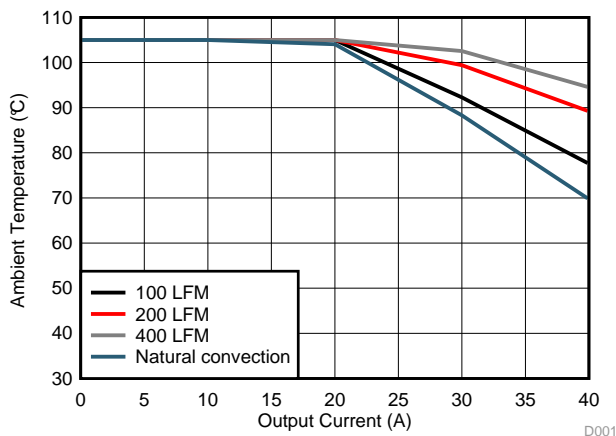
## Feature Description (continued)

### 7.3.2 On-Resistance

The typical on-resistance ( $R_{DS(on)}$ ) for the high-side MOSFET is 2.9 m $\Omega$  and typical on-resistance for the low-side MOSFET is 1.2 m $\Omega$  with a nominal gate voltage ( $V_{GS}$ ) of 5 V.

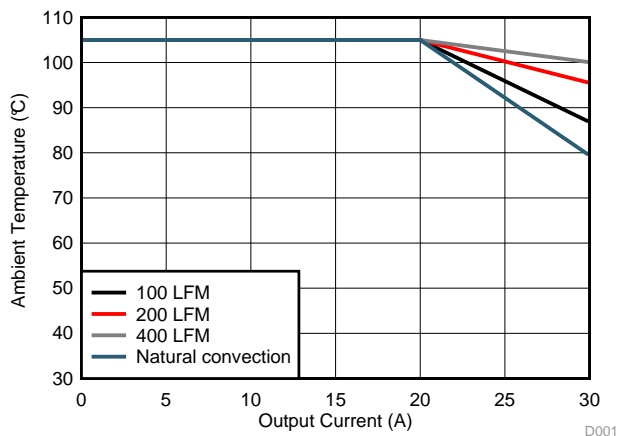
### 7.3.3 Package Size, Efficiency and Thermal Performance

The TPS549D22 device is available in a 7 mm  $\times$  5 mm, LQFN-CLIP package with 40 power and I/O pins. It employs TI proprietary MCM packaging technology with thermal pad. With a properly designed system layout, applications achieve optimized safe operating area (SOA) performance. The curves shown in Figure 23 and Figure 24 are based on the orderable evaluation module design. (See SLUUBG4 to order the EVM).



$V_{IN} = 12\text{ V}$        $V_{OUT} = 1\text{ V}$        $f_{SW} = 650\text{ kHz}$

**Figure 23. Safe Operating Area**



$V_{IN} = 12\text{ V}$        $V_{OUT} = 5.5\text{ V}$        $f_{SW} = 425\text{ kHz}$

**Figure 24. Safe Operating Area**

### 7.3.4 Soft-Start Operation

In the TPS549D22 device the soft-start time controls the inrush current required to charge the output capacitor bank during startup. The device offers selectable soft-start options of 1 ms, 2 ms, 4 ms and 8 ms. When the device is enabled (either by EN or VDD UVLO), the reference voltage ramps from 0 V to the final level defined by VSEL pin strap configuration, in a given soft-start time. The TPS549D22 device supports several soft-start times between 1msec and 8msec selected by MODE pin configuration. Refer to MODE definition table for details.

### 7.3.5 V<sub>DD</sub> Supply Undervoltage Lockout (UVLO) Protection

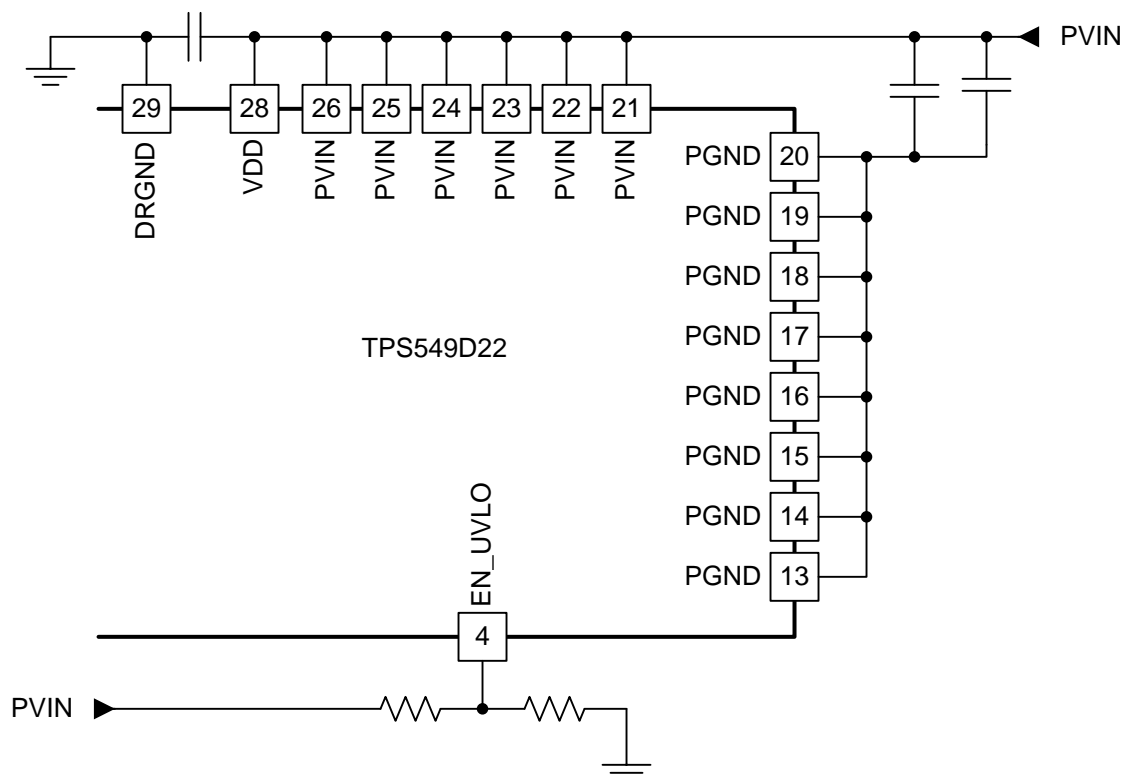
The TPS549D22 device provides fixed VDD undervoltage lockout threshold and hysteresis. The typical VDD turn-on threshold is 4.25 V and hysteresis is 0.2 V. The VDD UVLO can be used in conjunction with the EN\_UVLO signal to provide proper power sequence to the converter design. UVLO is a non-latched protection.

### 7.3.6 EN\_UVLO Pin Functionality

The EN\_UVLO pin drives an input buffer with accurate threshold and can be used to program the exact required turn-on and turn-off thresholds for switcher enable, VDD UVLO or VIN UVLO (if VIN and VDD are tied together). If desired, an external resistor divider can be used to set and program the turn-on threshold for VDD or VIN UVLO.

Figure 25 shows how to program the input voltage UVLO using the EN\_UVLO pin.

## Feature Description (continued)



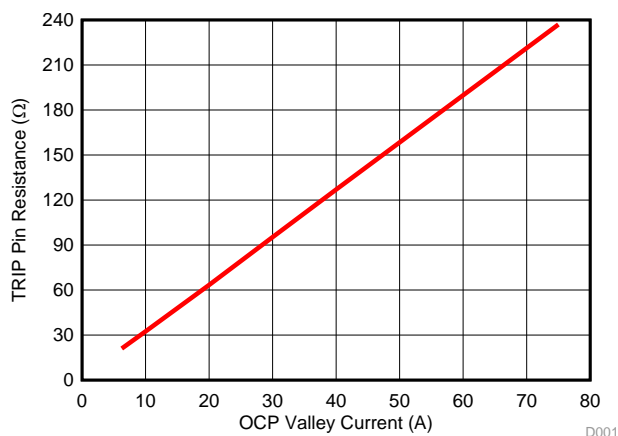
Copyright © 2016, Texas Instruments Incorporated

**Figure 25. Programming the UVLO Voltage**

### 7.3.7 Fault Protections

This section describes positive and negative overcurrent limits, overvoltage protections, out-of-bounds limits, undervoltage protections and over temperature protections.

#### 7.3.7.1 Current Limit (ILIM) Functionality



**Figure 26. Current Limit Resistance vs OCP Valley Overcurrent Limit**

The ILIM pin sets the OCP level. Connect the ILIM pin to GND through the voltage setting resistor,  $R_{ILIM}$ . In order to provide both good accuracy and cost effective solution, TPS549D22 device supports temperature compensated internal MOSFET  $R_{DS(on)}$  sensing.

## Feature Description (continued)

Also, the TPS549D22 device performs both positive and negative inductor current limiting with the same magnitudes. The positive current limit normally protects the inductor from saturation that causes damage to the high-side FET and low-side FET. The negative current limit protects the low-side FET during OVP discharge.

The voltage between GND pin and SW pin during the OFF time monitors the inductor current. The current limit has 3000 ppm/°C temperature slope to compensate the temperature dependency of the on-resistance ( $R_{DS(on)}$ ). The GND pin is used as the positive current sensing node.

TPS549D22 device uses cycle-by-cycle over-current limiting control. The inductor current is monitored during the OFF state and the controller maintains the OFF state during the period that the inductor current is larger than the overcurrent ILIM level.  $V_{ILIM}$  sets the valley level of the inductor current.

### 7.3.7.2 VDD Undervoltage Lockout (UVLO)

The TPS549D22 device has an UVLO protection function for the VDD supply input. The on-threshold voltage is 4.25 V with 200 mV of hysteresis. During a UVLO condition, the device is disabled regardless of the EN\_UVLO pin voltage. The supply voltage ( $V_{VDD}$ ) must be above the on-threshold to begin the pin strap detection.

### 7.3.7.3 Overvoltage Protection (OVP) and Undervoltage Protection (UVP)

The device monitors a feedback voltage to detect overvoltage and undervoltage. When the feedback voltage becomes lower than 68% of the target voltage, the UVP comparator output goes high and an internal UVP delay counter begins counting. After 1 ms, the device latches OFF both high-side and low-side MOSFETs drivers. The UVP function enables after soft-start is complete.

When the feedback voltage becomes higher than 120% of the target voltage, the OVP comparator output goes high and the circuit latches OFF the high-side MOSFET driver and turns on the low-side MOSFET until reaching a negative current limit. Upon reaching the negative current limit, the low-side FET is turned off and the high-side FET is turned on again for a minimum on-time. The TPS549D22 device operates in this cycle until the output voltage is pulled down under the UVP threshold voltage for 1 ms. After the 1-ms UVP delay time, the high-side FET is latched off and low-side FET is latched on. The fault is cleared with a reset of VDD or by retoggling the EN pin.

**Table 1. Overvoltage Protection Details**

REFERENCE VOLTAGE ( $V_{REF}$ )	SOFT-START RAMP	STARTUP OVP THRESHOLD	OPERATING OVP THRESHOLD	OVP DELAY 100 mV OD ( $\mu$ s)	OVP RESET
Internal	Internal	$1.2 \times \text{Internal } V_{REF}$	$1.2 \times \text{Internal } V_{REF}$	1	UVP

### 7.3.7.4 Out-of-Bounds Operation

The device has an out-of-bounds (OOB) overvoltage protection that protects the output load at a much lower overvoltage threshold of 8% above the target voltage. OOB protection does not trigger an overvoltage fault, so the device is not latched off after an OOB event. OOB protection operates as an early no-fault overvoltage-protection mechanism. During the OOB operation, the controller operates in forced PWM mode only by turning on the low-side FET. Turning on the low-side FET beyond the zero inductor current quickly discharges the output capacitor thus causing the output voltage to fall quickly toward the setpoint. During the operation, the cycle-by-cycle negative current limit is also activated to ensure the safe operation of the internal FETs.

### 7.3.7.5 Overtemperature Protection

TPS549D22 device has overtemperature protection (OTP) by monitoring the die temperature. If the temperature exceeds the threshold value (default value 165°C), TPS549D22 device is shut off. When the temperature falls about 25°C below the threshold value, the device turns on again. The OTP is a non-latch protection.

## 7.4 Device Functional Modes

### 7.4.1 DCAP3 Control Topology

The TPS549D22 employs an artificial ramp generator that stabilizes the loop. The ramp amplitude is automatically adjusted as a function of selected switching frequency ( $f_{sw}$ ). The ramp amplitude is a function of duty cycle ( $V_{OUT}$ -to- $V_{IN}$  ratio). Consequently, two additional pin-strap bits (ADDR[2:1]) are provided for fine tuning the internal ramp amplitude. The device uses an improved DCAP3 control loop architecture that incorporates a steady-state error integrator. The slow integrator improves the output voltage DC accuracy greatly and presents minimal impact to small signal transient response. To further enhance the small signal stability of the control loop, the device uses a modified ramp generator that supports a wider range of output LC stage.

### 7.4.2 DCAP Control Topology

For advanced users of this device, the internal DCAP3 ramp can be disabled using the MODE[4] pin strap bit. This situation requires an external RCC network to ensure control loop stability. Place this RCC network across the output inductor. Use a range between 10 mV and 15 mV of injected RSP pin ripple. If no feedback resistor divider network is used, insert a 10-k $\Omega$  resistor between the VOUT pin and the RSP pin.

## 7.5 Programming

### 7.5.1 Programmable Pin-Strap Settings

ADDR, VSEL and MODE. Description: a 1% or better 100-k $\Omega$  resistor is needed from BP to each of the three pins. The bottom resistor from each pin to ground (see **MODE**, **VSEL**, **ADDR DETECTION** section of the [Electrical Characteristics](#) table) in conjunction with the top resistor defines each pin strap selection. The pin detection checks for external resistor divider ratio during initial power up (VDD is brought down below approximately 3 V) when BP LDO output is at approximately 2.9 V.

#### 7.5.1.1 Address Selection (ADDR) Pin

The TPS549D22 allows up to 16 different chip addresses for PMBus communication with the first 3 bits fixed as 001. The address selection process is defined by resistor divider ratio from BP pin to ADDR pin, and the address detection circuit will start to work only after the initial power up when VDD has risen above its UVLO threshold. lists all combinations of the address selections. The 1% or better tolerance resistors with typical temperature coefficient of  $\pm 100$ ppm/ $^{\circ}$ C are recommended.

ADDR pin strap configuration also programs the light load conduction mode.



## Programming (continued)

### 7.5.1.2 VSEL Pin

VSEL pin strap configuration is used to program initial boot voltage value, hiccup mode and latch off mode. The initial boot voltage is used to program the main loop voltage reference point. VSEL voltage settings provide TI designated discrete internal reference voltages. [Table 2](#) lists internal reference voltage selections.

**Table 2. Internal Reference Voltage Selections**

VSEL[4]	VSEL[3]	VSEL[2]	VSEL[1]	VSEL[0]	R <sub>VSEL</sub> (kΩ) <sup>(1)</sup>
1111: <b>0.975 V</b>				1: Latch-Off	Open
				0: Hiccup	187
1110: 1.1992 V				1: Latch-Off	165
				0: Hiccup	147
1101: 1.1504 V				1: Latch-Off	133
				0: Hiccup	121
1100: 1.0996 V				1: Latch-Off	110
				0: Hiccup	100
1011: 1.0508 V				1: Latch-Off	90.9
				0: Hiccup	82.5
1010: 1.0000 V				1: Latch-Off	75
				0: Hiccup	68.1
1001: 0.9492 V				1: Latch-Off	60.4
				0: Hiccup	53.6
1000: 0.9023 V				1: Latch-Off	47.5
				0: Hiccup	42.2
0111: 0.9004 V				1: Latch-Off	37.4
				0: Hiccup	33.2
0110: 0.8496 V				1: Latch-Off	29.4
				0: Hiccup	25.5
0101: 0.8008 V				1: Latch-Off	22.1
				0: Hiccup	19.1
0100: 0.7500 V				1: Latch-Off	16.5
				0: Hiccup	14.3
0011: 0.6992 V				1: Latch-Off	12.1
				0: Hiccup	10
0010: 0.6504 V				1: Latch-Off	7.87
				0: Hiccup	6.19
0001: 0.5996 V				1: Latch-Off	4.64
				0: Hiccup	3.16
0000: <b>0.975 V</b>				1: Latch-Off	1.78
				0: Hiccup	0

(1) 1% or better and connect to ground

### 7.5.1.3 DCAP3 Control and Mode Selection

The MODE pinstrap configuration programs the control topology and internal soft-start timing selections. The TPS549D22 device supports both DCAP3 and DCAP operation

MODE[4] selection bit is used to set the control topology. If MODE[4] bit is “0”, it selects DCAP operation. If MODE[4] bit is “1”, it selects DCAP3 operation.

MODE[1] and MODE[0] selection bits are used to set the internal soft-start timing

**Table 3. Allowable MODE Pin Selections**

MODE[4]	MODE[3]	MODE[2]	MODE[1]	MODE[0]	R <sub>MODE</sub> (kΩ) <sup>(1)</sup>
1: DCAP3	0: Internal Reference	0: Internal SS	11: 8 ms <sup>(2)</sup>		60.4
			10: 4 ms <sup>(2)</sup>		53.6
			01: 2 ms		47.5
			00: 1 ms		42.2
0: DCAP			11: 8 ms <sup>(2)</sup>		4.64
			10: 4 ms <sup>(2)</sup>		3.16
			01: 2 ms		1.78
			00: 1 ms		0

(1) 1% or better and connect to ground

(2) See [Application Workaround to Support 4-ms and 8-ms SS Settings](#).

### 7.5.1.4 Application Workaround to Support 4-ms and 8-ms SS Settings

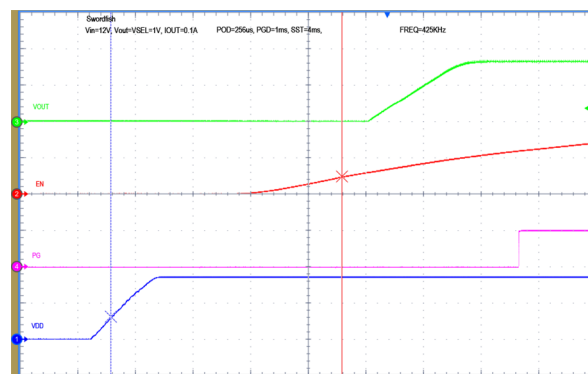
In order to properly design for 4-ms and 8-ms SS settings, additional application consideration is needed. The recommended application workaround to support the 4-ms and 8-ms soft-start settings is to ensure sufficient time delay between the VDD and EN\_UVLO signals. The minimum delay between the rising maximum VDD\_UVLO level and the minimum turnon threshold of EN\_UVLO is at least T<sub>DELAY\_MIN</sub>.

$$T_{\text{DELAY\_MIN}} = K \times V_{\text{REF}}$$

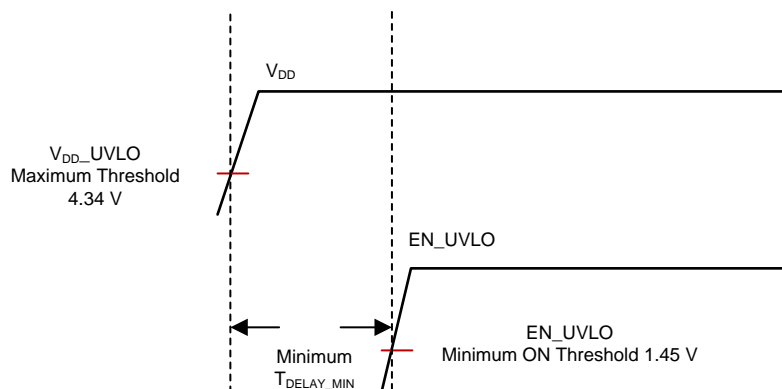
where

- K = 9 ms/V for SS setting of 4 ms
  - K = 18 ms/V for SS setting of 8 ms
  - V<sub>REF</sub> is the internal reference voltage programmed by VSEL pin strap
- (1)

For example, if SS setting is 4 ms and V<sub>REF</sub> = 1 V, program the minimum delay at least 9 ms; if SS setting is 8 ms, the minimum delay should be programmed at least 18 ms. See [Figure 27](#) and [Figure 28](#) for detailed timing requirement. Because TPS549D22 is a PMBus device, the end user has the option of programming power-on delay (POD) as another workaround. Be sure to follow the same calculation to determine the required POD (see [MFR\\_SPECIFIC\\_01 \(address = D1h\)](#) and [Table 25](#) for more information).



**Figure 27. Proper Sequencing of V<sub>DD</sub> and EN\_UVLO to Support the Use of 4-ms SS Setting**



**Figure 28. Minimum Delay Between V<sub>DD</sub> and EN\_UVLO to Support the Use of 4-ms and 8-ms SS settings**

The workaround/consideration described previously is not required for SS settings of 1 ms and 2 ms.

## 7.5.2 Programmable Analog Configurations

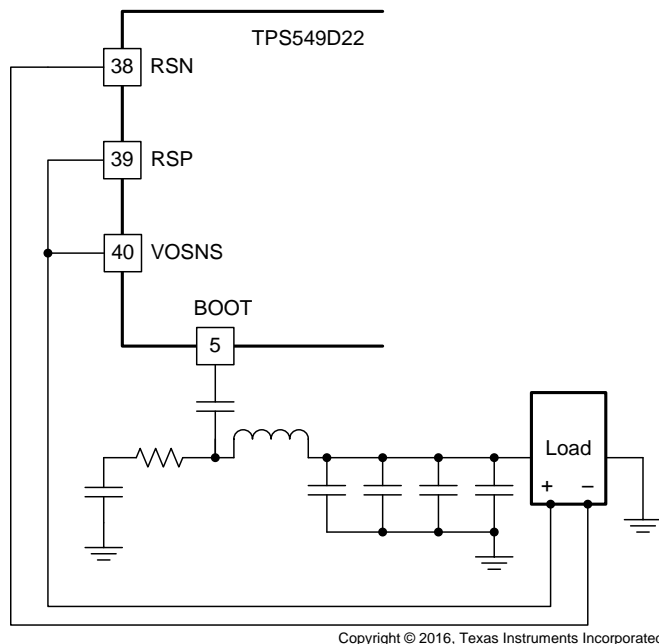
### 7.5.2.1 RSP/RSN Remote Sensing Functionality

RSP and RSN pins are used for remote sensing purpose. In the case where feedback resistors are required for output voltage programming, the RSP pin should be connected to the mid-point of the resistor divider and the RSN pin should always be connected to the load return. In the case where feedback resistors are not required as when the VSEL programs the output voltage set point, the RSP pin should be connected to the positive sensing point of the load and the RSN pin should always be connected to the load return.

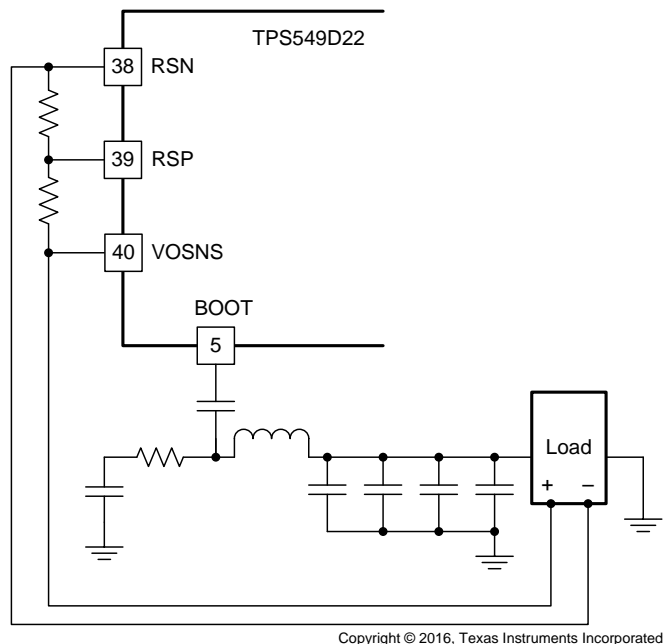
RSP and RSN pins are extremely high-impedance input terminals of the true differential remote sense amplifier. The feedback resistor divider should use resistor values much less than 100 k $\Omega$ .

#### 7.5.2.1.1 Output Differential Remote Sensing Amplifier

The examples in this section show simplified remote sensing circuitry where each example uses an internal reference of 1 V. [Figure 29](#) shows remote sensing without feedback resistors, with an output voltage set point of 1 V. [Figure 30](#) shows remote sensing using feedback resistors, with an output voltage set point of 5 V.



**Figure 29. Remote Sensing Without Feedback Resistors**



**Figure 30. Remote Sensing With Feedback Resistors**

### 7.5.2.2 Power Good (PGOOD Pin) Functionality

The TPS549D22 device has power-good output that registers high when switcher output is within the target. The power-good function is activated after soft-start has finished. When the soft-start ramp reaches 300 mV above the internal reference voltage, SSend signal goes high to enable the PGOOD detection function. If the output voltage becomes within  $\pm 8\%$  of the target value, internal comparators detect power-good state and the power good signal becomes high after a 1-ms programmable delay. If the output voltage goes outside of  $\pm 16\%$  of the target value, the power good signal becomes low after two microsecond (2- $\mu$ s) internal delay. The open-drain power-good output must be pulled up externally. The internal N-channel MOSFET does not pull down until the VDD supply is above 1.2 V.

### 7.5.3 PMBus Programming

TPS549D22 has seven internal custom user-accessible 8-bit registers. The PMBus interface has been designed for program flexibility, supporting direct format for write operation. Read operations are supported for both combined format and stop separated format. While there is no auto increment/decrement capability in the TPS549D22 PMBus logic, a tight software loop can be designed to randomly access the next register independent of which register was accessed first. The start and stop commands frame the data packet and the repeat start condition is allowed when necessary.

#### 7.5.3.1 TPS549D22 Limitations to the PMBUS Specifications

TPS549D22 only recognizes seven bit addressing. This means TPS549D22 is not compatible with ten bit addressing and CBUS communication. The device can operate in standard mode (100 kbit/s), fast mode (400 kbit/s) or faster mode (1000 kbit/s).

#### 7.5.3.2 Slave Address Assignment

The seven bit slave address is  $001A_3A_2A_1A_0x$ , where  $A_3A_2A_1A_0$  is set by the ADDR pin on the device. Bit 0 is the data direction bit, i.e.  $001A_3A_2A_1A_00$  is used for write operation and  $001A_3A_2A_1A_01$  is used for read operation.

#### 7.5.3.3 PMBUS Address Selection

TPS549D22 allows up to 16 different chip addresses for PMBus communication, with the first three bits fixed as 001. The address selection process is defined by the resistor divider ratio from BP pin to ADDR pin, and the address detection circuit will start to work only after VDD input supply has risen above its UVLO threshold. [Table 4](#) lists the divider ratio and some example resistor values. The 1% tolerance resistors with typical temperature coefficient of  $\pm 100$  ppm/°C are recommended. Higher performance resistors can be used if tighter noise margin is required for more reliable address detection.

#### 7.5.3.4 Supported Formats

The supported formats are described in the following subsections.

##### 7.5.3.4.1 Direct Format — Write

The simplest format for a PMBus write is direct format. After the start condition [S], the slave chip address is sent, followed by an eighth bit indicating a write. TPS549D22 then acknowledges that it is being addressed, and the master responds with an 8 bit register address byte. The slave acknowledges and the master sends the appropriate 8 bit data byte. Once again the slave acknowledges and the master terminates the transfer with the stop condition [P].

##### 7.5.3.4.2 Combined Format — Read

After the start condition [S], the slave chip address is sent, followed by an eighth bit indicating a write. TPS549D22 then acknowledges that it is being addressed, and the master responds with an 8 bit register address byte. The slave acknowledges and the master sends the repeated start condition [Sr]. Once again, the slave chip address is sent, followed by an eighth bit indicating a read. The slave responds with an acknowledge followed by previously addressed 8 bit data byte. The master then sends a non-acknowledge (NACK) and finally terminates the transfer with the stop condition [P].

#### 7.5.3.5 Stop Separated Reads

Stop-separated reads can also be used. This format allows a master to set up the register address pointer for a read and return to that slave at a later time to read the data. In this format the slave chip address followed by a write bit are sent after a start [S] condition. TPS549D22 then acknowledges it is being addressed, and the master responds with the 8-bit register address byte. The master then sends a stop or restart condition and may then address another slave. After performing other tasks, the master can send a start or restart condition to the TPS549D22 with a read command. The device acknowledges this request and returns the data from the register location that had been set up previously.

**Table 4. ADDR Pin Selection Table**

PMBus_Address<3:0>				CM	RADDR (k $\Omega$ ) (1% or better and connect to ground)
1	1	1	1	1: FCCM	Open
				0: SKIP	187
1	1	1	0	1: FCCM	165
				0: SKIP	147
1	1	0	1	1: FCCM	133
				0: SKIP	121
1	1	0	0	1: FCCM	110
				0: SKIP	100
1	0	1	1	1: FCCM	90.9
				0: SKIP	82.5
1	0	1	0	1: FCCM	75
				0: SKIP	68.1
1	0	0	1	1: FCCM	60.4
				0: SKIP	53.6
1	0	0	0	1: FCCM	47.5
				0: SKIP	42.2
0	1	1	1	1: FCCM	37.4
				0: SKIP	33.2
0	1	1	0	1: FCCM	29.4
				0: SKIP	25.5
0	1	0	1	1: FCCM	22.1
				0: SKIP	19.1
0	1	0	0	1: FCCM	16.5
				0: SKIP	14.3
0	0	1	1	1: FCCM	12.1
				0: SKIP	10
0	0	1	0	1: FCCM	7.87
				0: SKIP	6.19
0	0	0	1	1: FCCM	4.64
				0: SKIP	3.16
0	0	0	0	1: FCCM	1.78
				0: SKIP	0

### 7.5.3.6 Supported PMBUS Commands and Registers

Only the following PMBus commands are supported by TPS549D22, and not all parts of each command are supported.

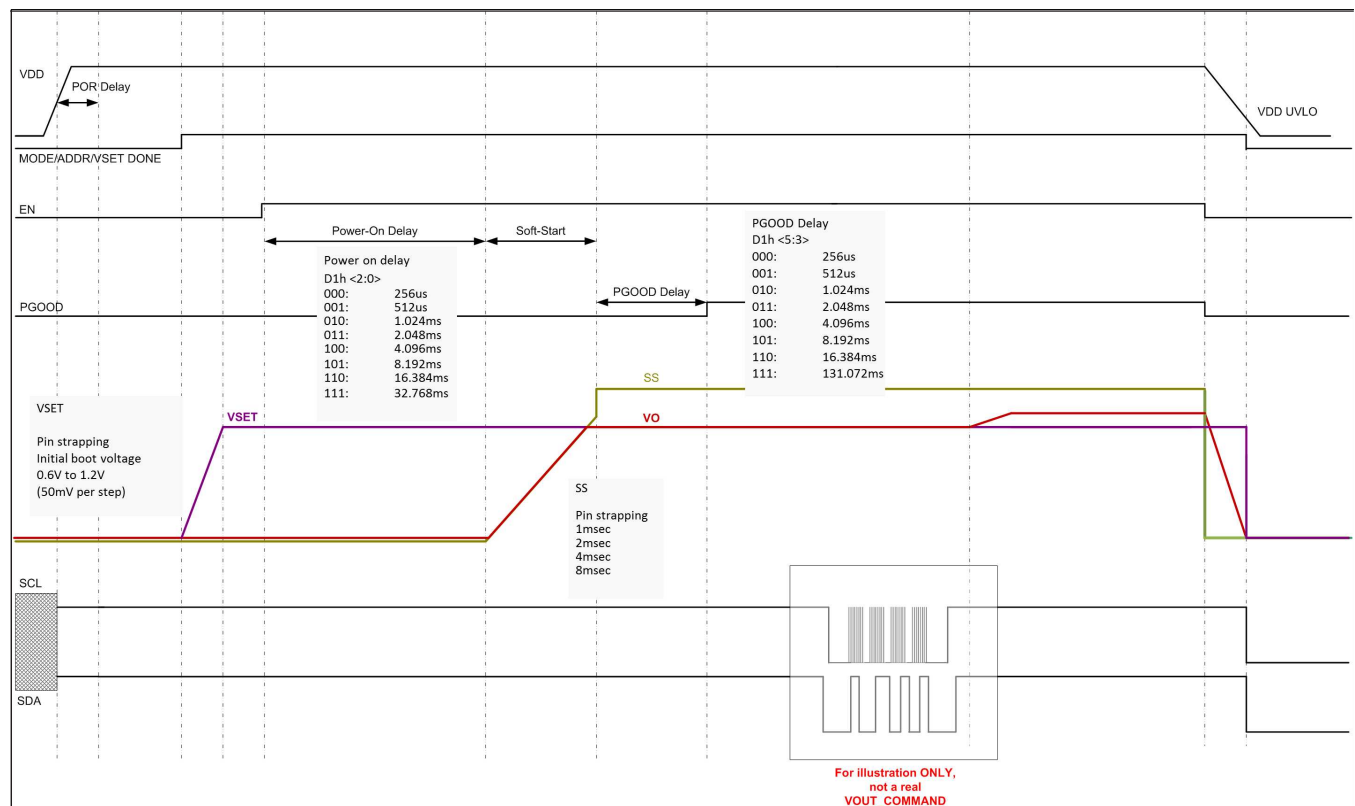
**Table 5. PMBUS Command and Register Table**

CMD CODE	COMMAND NAME	DESCRIPTION	NVM?	TYPE	No. of DATA BYTES	BIT PATTERN
1h	OPERATION	The OPERATION command is used to turn the unit on and off in conjunction with the input from the EN pin. It is also used to cause the device to set the output voltage to the upper or lower Margin voltages.	no	R/W Byte	1	00XX XX00 = Turn Off 1000 XX00 = Turn on (VOUT Margin off) 1001 0100 = Turn on (VOUT Margin Low, Ignore Fault) 1001 1000 = Turn on (VOUT Margin Low, Act on Fault) 1010 0100 = Turn on (VOUT Margin High, Ignore Fault) 1010 1000 = Turn on (VOUT Margin High, Act on Fault)
2h	ON_OFF_CONFIG	Configures the combination of EN pin input and serial bus commands needed to turn the unit on and off. This includes how the unit responds when power is applied.	yes	R/W Byte	1	0001 0011 = Act on neither OPERATION nor EN pin 0001 0111 = Act on EN pin and ignore OPERATION 0001 1011 = Act on OPERATION and ignore EN pin 0001 1111 = Act on OPERATION and Act on EN pin (requires both)
3h	CLEAR_FAULTS	Clears all fault status registers to 0x00 and deasserts SMBAlert. The "Unit is Off" bit in the status byte and "PGOOD# de-assertion" bit in the status word are not cleared when this command is issued.	no	Send Byte	0	No data. Write only.
10h	WRITE_PROTECT	Prevents unwanted writes to the device. This register can be over-written. This is not a permanent lock.	yes	R/W Byte	1	1000 0000 Only allow WRITE_PROTECT 0100 0000 Only allow WRITE_PROTECT and OPERATION 0010 0000 Only allow WRITE_PROTECT, OPERATION, ON_OFF_CONFIG and VOUT_COMMAND 0000 0000 Allow all writes
11h	STORE_DEFAULT_ALL	Copies Operating Memory to matching non-volatile Default Store Memory.	no	Send Byte	0	No data. Write only.
12h	RESTORE_DEFAULT_ALL	Restores all parameters from non-volatile Default Store Memory to Operating Memory	no	Send Byte	0	No data. Write only.
19h	CAPABILITY	This command provides a way for a host system to determine some key capabilities of a PMBus device, including PEC, Alert and Speed.	no	Read Byte	1	1101 0000 = PEC, 1MHz bus speed, ALERT
20h	VOUT_MODE	Hard coded to linear mode with exponent of -9.	no	Read Byte	1	000x xxxx = Linear format. 0001 0111 = Exponent value of -9 (1.953mV resolution)
21h	VOUT_COMMAND	Output voltage setpoint. DAC resolution is 1.9531mV and range is -0.6V to -1.200V	yes	R/W Word	2	0000 0001 0011 0011 = 0.5996V 0000 0010 0110 0110 = 1.1992V
25h	VOUT_MARGIN_HIGH	Sets the voltage to which the output is to be changed when the OPERATION command is set to "MARGIN HIGH".	no	R/W Word	2	0000 0001 0011 0011 = 0.5996V 0000 0010 0110 0110 = 1.1992V
26h	VOUT_MARGIN_LOW	Sets the voltage to which the output is to be changed when the OPERATION command is set to "MARGIN LOW".	no	R/W Word	2	0000 0001 0011 0011 = 0.5996V 0000 0010 0110 0110 = 1.1992V
78h	STATUS_BYTE	Status of all fault conditions in a data byte.	no	Read Byte	1	See Status Word Table
79h	STATUS_WORD	Status of all fault conditions in two data bytes.	no	Read Word	2	See Status Word Table
7Ah	STATUS_VOUT	Returns one byte of information relating to the status of the output voltage related faults.	no	Read Byte	1	See Status Vout Table
7Bh	STATUS_OUT	Returns one byte of information relating to the status of the output current related faults.	no	Read Byte	1	See Status Iout Table



**Table 5. PMBUS Command and Register Table (continued)**

CMD CODE	COMMAND NAME	DESCRIPTION	NVM?	TYPE	No. of DATA BYTES	BIT PATTERN
7Eh	STATUS_CML	Status of communications, logic and memory in a data byte	no	Read Byte	1	XXX0 0000 0XX0 0000 = A valid or supported command has been received 1XX0 0000 = An invalid or unsupported command has been received X0X0 0000 = A valid or supported data has been received X1X0 0000 = An invalid or unsupported data has been received XX00 0000 = Packet error check has failed XX10 0000 = Packet error check has succeeded
D0h	MFR_SPECIFIC_00	Customer programmable byte that does not affect chip functionality	yes	R/W Byte	1	Free format
D1h	MFR_SPECIFIC_01	Program PGOOD delay and Power-On delay	yes	R/W Byte	1	
D2h	MFR_SPECIFIC_02	Read SST, CM, HICLOFF, TRK and SEQ. Program Forced SKIP Soft Start.	yes	R/W Byte	1	
D3h	MFR_SPECIFIC_03	Program Fsw and control mode, Read RC ramp	yes	R/W Byte	1	
D4h	MFR_SPECIFIC_04	Program the DCAP3 offset	yes	R/W Byte	1	
D6h	MFR_SPECIFIC_06	Program the VDD UVLO level	yes	R/W Byte	1	
D7h	MFR_SPECIFIC_07	Program the final tracking set point and select pseudo/external tracking	yes	R/W Byte	1	
FCh	MFR_SPECIFIC_44	Read TI PMBUS GUI Devcie ID and IC revision code	no	Read Word	2	


**Figure 31. Startup and VOUT\_COMMAND Timing Diagram**

**Table 6. Status Word Summary Table**

<b>BITS</b>	<b>NAME</b>	<b>MEANING</b>
Low 7	not used	not used
Low 6	OFF	Unit is not providing power to the output
Low 5	VOUT_OV_FAULT	Output overvoltage
Low 4	IOUT_OC_FAULT	Output overcurrent
Low 3	VDD_UV_FAULT	Input VDD undervoltage
Low 2	TEMP	Internal die temperature. Over temperature fault
Low 1	CML	Communications, logic or memory fault
Low 0	OTHER	None of the above in the PMBUS spec
High 7	VOUT	Any output voltage fault or warning
High 6	IOUT	Any output current fault or warning
High 5	VDD_UV_FAULT	Input VDD undervoltage
High 4	not used	Not used
High 3	PGOOD#	Power good de-asserted
High 2	not used	not used
High 1	not used	not used
High 0	not used	not used

**Table 7. Status V<sub>OUT</sub> Summary Table**

<b>BITS</b>	<b>NAME</b>	<b>MEANING</b>
7	OVF	Over voltage fault
6	OVW	Over voltage warning
5	UVW	Under voltage warning
4	UVF	Under voltage fault
3	not used	not used
2	not used	not used
1	not used	not used

**Table 8. Status I<sub>OUT</sub> Summary Table**

<b>BITS</b>	<b>NAME</b>	<b>MEANING</b>
7	OCF	Over current fault
6	OCUVF	Over current and output undervoltage fault
5	not used	not used
4	UCF	Negative over current limit
3	not used	not used
2	not used	not used
1	not used	not used
0	not used	not used

## 7.5.4 Register Maps

### 7.5.4.1 OPERATION Register (address = 1h)

**Figure 32. OPERATION**

7	6	5	4	3	2	1	0
On_OFF	0	OPMARGIN<3:0>				0	0
R/W	R/W	R/W				R	R

RLEGEND: R/W = Read/Write; R = Read only; -n = value after reset

**Table 9. OPERATION**

Bit	Field	Type	Reset	Description
7	ON_OFF	R/W	0	0: Turn off switching converter (if CMD=1) 1: Turn on switching converter (if CMD=1), and also enable VOUT Margin function
6		R	0	
5:2	OPMARGIN<3:0>	R/W	0	00xx: Turn off VOUT Margin function 0101: Turn on VOUT Margin Low and Ignore Fault 0110: Turn on VOUT Margin Low and Act On Fault 1001: Turn on VOUT Margin High and Ignore Fault 1010: Turn on VOUT Margin High and Act On Fault
1		R	0	
0		R	0	

### 7.5.4.2 ON\_OFF\_CONFIG Register (address = 2h)

**Figure 33. ON\_OFF\_CONFIG**

7	6	5	4	3	2	1	0
0	0	0	1	CMD	CP	1	1
R	R	R	R	R/W	R/W	R	R

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

**Table 10. ON\_OFF\_CONFIG**

Bit	Field	Type	Reset	Description
7		R	0	
6		R	0	
5		R	0	
4		R	1	
3	CMD	R/W	0	0: Ignore ON_OFF bit 1: Act on ON_OFF bit
2	CP	R/W	1	0: Ignore ON_OFF bit 1: Act on ON_OFF bit
1		R	1	
0		R	1	

### 7.5.4.3 CLEAR FAULTS (address = 3h)

The CLEAR\_FAULTS command is used to clear any fault bits that have been set. This command simultaneously clears all bits in all status registers. At the same time, the device clears its SMB\_ALERT# signal output if the device is asserting the SMB\_ALERT# signal.

The CLEAR\_FAULTS command does not cause a unit that has latched off for a fault condition to restart. If the fault is still present when the bit is cleared, the fault bit shall immediately be set again and the host notified by the usual means.

#### 7.5.4.4 WRITE PROTECT (address = 10h)

**Figure 34. WRITE PROTECT**

7	6	5	4	3	2	1	0
0	0	0	0	0	0	0	0
R/W	R/W	R/W	R	R	R	R	R

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

**Table 11. WRITE PROTECT**

Bit	Field	Type	Reset	Description
7:0	WRITE_PROTECT	R/W	0	00000000: Enable writes to ALL commands 00100000: Enable writes to only WRITE_PROTECT, OPERATION and ON_OFF_CONFIG and VOUT_COMMAND commands 01000000: Enable writes to only WRITE_PROTECT and OPERATION 10000000: Enable writes to only WRITE_PROTECT

#### 7.5.4.5 STORE\_DEFAULT\_ALL (address = 11h)

Store all of the current storable register settings in the EEPROM memory as the new defaults on power up.

It is permitted to use the STORE\_DEFAULT\_ALL command while the device is operating. However, the device may be unresponsive during the write operation with unpredictable memory storage results. TI recommends to turn the device output off before issuing this command.

EEPROM programming faults will set the 'CML' bit in the STATUS\_BYTE and the 'MEM' bit in the STATUS\_CML registers.

#### 7.5.4.6 RESTORE\_DEFAULT\_ALL (address = 12h)

Write EEPROM data to those CSRs that: (1) have EEPROM support, and; (2) are unprotected according to current setting of WRITE\_PROTECT.

It is permitted to use the RESTORE\_DEFAULT\_ALL command while the device is operating. However, the device may be unresponsive during the copy operation with unpredictable, undesirable or even catastrophic results. TI recommends to turn the device output off before issuing this command.

No data bytes are sent, just the command code is sent.

#### 7.5.4.7 CAPABILITY (address = 19h)

This command provides a way for a host system to determine some key capabilities of this PMBus device.

**Figure 35. CAPABILITY**

7	6	5	4	3	2	1	0
PEC=1	SPEED <1:0>		ALRT=1	0	0	0	0
R	R	R	R	R	R	R	R

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

**Table 12. CAPABILITY**

Bit	Field	Type	Reset	Description
7	PEC=1	R	1	1: Packet Error Checking is supported
6:5	SPEED <1:0>	R	10b	10: Maximum supported bus speed is 1 MHz
4	ALRT=1	R	1	TPS549D22 has an ALERT# pin and it supports SMBus Alert Response protocol
3		R	0	
2		R	0	
1		R	0	
0		R	0	

### 7.5.4.8 VOUT\_MODE (address = 20h)

**Figure 36. VOUT\_MODE**

7	6	5	4	3	2	1	0
MODE = 000			Exponent = 10111				
R	R	R	R	R	R	R	R

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

**Table 13. VOUT\_MODE**

Bit	Field	Type	Reset	Description
7:5	MODE = 000	R	0	000: Linear Format
4:0	Exponent	R	17h	10111: Exponent = -9 (equivalent of 1.9531 mV/LSB)

### 7.5.4.9 VOUT\_COMMAND (address = 21h)

The VOUT\_COMMAND command sets the output voltage in volts. The exponent is set be VOUT\_MODE at -9 (equivalent of 1.9531 mV/LSB). The programmed  $V_{OUT}$  is computed as:

$$V_{OUT} = VOUT\_COMMAND \times VOUT\_MODE \text{ volts} = VOUT\_COMMAND \times 2^{-9} \text{ V} \quad (2)$$

The support range for TPS549D22 is: 0.5996 V to 1.1992 V. It is effectively 9-bits limited to 307 to 614 decimal. Slew rate control is provided through MODE pin.

$V_{OUT}$  setps 1 step/ $t_{slew}$ , where  $t_{slew}$  is programmable by MODE pin: 4, 8, 16, or 32  $\mu$ s.

**Figure 37. VOUT\_COMMAND**

7	6	5	4	3	2	1	0	7	6	5	4	3	2	1	0
Mantissa															
R	R	R	R	R	R	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

**Table 14. VOUT\_COMMAND**

Bit	Field	Type	Reset	Description
7:4	Mantissa	R	0000	
3:0	Mantissa	R/W	00xx	x = pin strap
7:0	Mantissa	R/W	xxxx xxxx	

### 7.5.4.10 VOUT\_MARGIN\_HIGH (address = 25h)

The VOUT\_MARGIN\_HIGH command loads the TPS549D22 with the voltage to which the output is to be changed when the OPERATION command is set to "Margin High".

The data bytes are two bytes formatted according to the setting of the VOUT\_MODE command.

The support margin range for TPS549D22 is: 0.5996 V to 1.1992 V. It is effectively 9-bits limited to 307 to 614 decimal. Slew rate control is provided through MODE pin.

**Figure 38. VOUT\_MARGIN\_HIGH**

7	6	5	4	3	2	1	0	7	6	5	4	3	2	1	0
Mantissa															
R	R	R	R	R	R	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

**Table 15. VOUT\_MARGIN\_HIGH**

Bit	Field	Type	Reset	Description
7:4	Mantissa	R	0000	
3:0	Mantissa	R/W	00xx	x = pin strap
7:0	Mantissa	R/W	xxxx xxxx	

#### 7.5.4.11 VOUT\_MARGIN\_LOW (address = 26h)

The VOUT\_MARGIN\_LOW command loads the TPS549D22 with the voltage to which the output is to be changed when the OPERATION command is set to “Margin Low”.

The data bytes are two bytes formatted according to the setting of the VOUT\_MODE command.

The support margin range for TPS549D22 is: 0.5996 V to 1.1992 V. It is effectively 9-bits limited to 307 to 614 decimal. Slew rate control is provided through MODE pin.

**Figure 39. VOUT\_MARGIN\_LOW:**

7	6	5	4	3	2	1	0	7	6	5	4	3	2	1	0
Mantissa															
R	R	R	R	R	R	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

**Table 16. VOUT\_MARGIN\_LOW:**

Bit	Field	Type	Reset	Description
7:4	Mantissa	R	0000	
3:0	Mantissa	R/W	00xx	x = pin strap
7:0	Mantissa	R/W	xxxx xxxx	

#### 7.5.4.12 STATUS\_BYTE (address = 78h)

**Figure 40. STATUS\_BYTE**

7	6	5	4	3	2	1	0
Not used	OFF	VOUT_OV	IOUT_OC	VDD_UV	TEMP	CML	OTHER
R	R	R	R	R	R	R	R

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

**Table 17. STATUS\_BYTE**

Bit	Field	Type	Reset	Description
7	Not Used	R	N/A	Not Used
6	OFF	R	N/A	0: IC is on. This includes the following fault response conditions where the output is still being actively driven, such as OVP and OCF. 1: IC is off. This includes two conditions. One is unit is commanded off via OPERATION/ON_OFF_CONFIG and the other is unit is commanded on via OPERATION/ON_OFF_CONFIG; but, due to fault response the output has been tri-stated by UVF, OT and UVLO.
5	VOUT_OV	R	N/A	0: An output overvoltage fault has not occurred 1: An output overvoltage fault has occurred
4	IOUT_OC	R	N/A	0: An output overcurrent fault has not occurred 1: An output overcurrent fault has occurred
3	VDD_UV	R	N/A	0: An input undervoltage fault has not occurred 1: An input undervoltage fault has occurred
2	TEMP	R	N/A	0: A temperature fault or warning has not occurred 1: A temperature fault or warning has occurred
1	CML	R	N/A	0: A communications, memory or logic fault has not occurred 1: A communications, memory or logic fault has occurred
0	OTHER	R	N/A	0: A fault or warning not listed above has not occurred 1: A fault of warning not listed above has occurred

**7.5.4.13 STATUS\_WORD (High Byte) (address = 79h)**
**Figure 41. STATUS\_WORD (High Byte)**

7	6	5	4	3	2	1	0
VOUT	IOUT	VDD	Not Used	PGOOD#	Not Used		
R	R	R	R	R	R		

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

**Table 18. STATUS\_WORD (High Byte)**

Bit	Field	Type	Reset	Description
7	VOUT	R	N/A	0: An output voltage fault or warning has not occurred 1: An output voltage fault or warning has occurred
6	IOUT	R	N/A	0: An output current fault has not occurred 1: An output current fault has occurred
5	VDD	R	N/A	A VDD voltage fault has not occurred 1: A VDD voltage fault has occurred
4	Not Used	R	N/A	Not Used
3	PGOOD#	R	N/A	0: PGOOD pin is at logic high 1: PGOOD pin is at logic high
2:0	Not Used	R	N/A	Not used

#### 7.5.4.14 STATUS\_VOUT (address = 7Ah)

**Figure 42. STATUS\_VOUT**

7	6	5	4	3	2	1	0
OVF	OVW	UVW	UVF	Not Used			
R	R	R	R	R			

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

**Table 19. STATUS\_VOUT**

Bit	Field	Type	Reset	Description
7	OVF	R	N/A	0: An output overvoltage fault has not occurred 1: An output overvoltage fault has occurred
6	OVW	R	N/A	0: An output overvoltage warning has not occurred 1: An output overvoltage warning has occurred
5	UVW	R	N/A	0: An output undervoltage warning has not occurred 1: An output undervoltage warning has occurred
4	UVF	R	N/A	0: An output undervoltage fault has not occurred 1: An output undervoltage fault has occurred
3:0	Not Used	R	N/A	Not Used

#### 7.5.4.15 STATUS\_IOUT (address = 7Bh)

**Figure 43. STATUS\_IOUT**

7	6	5	4	3	2	1	0
OCF	OCUVF	Not Used	UCF	Not Used			
R	R	R	R	R			

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

**Table 20. STATUS\_IOUT**

Bit	Field	Type	Reset	Description
7	OCF	R	N/A	0: An output positive overcurrent fault has not occurred 1: An output positive overcurrent fault has occurred
6	OCUVF	R	N/A	0: A simultaneous output positive overcurrent and undervoltage fault has not occurred 1: A simultaneous output positive overcurrent and undervoltage fault has occurred
5	Not Used	R	N/A	Not Used
4	UCF	R	N/A	0: An output negative overcurrent fault has not occurred 1: An output negative overcurrent fault has occurred
3:0	Not Used	R	N/A	Not Used



**7.5.4.16 STATUS\_CML (address = 7Eh)**
**Figure 44. STATUS\_CML**

7	6	5	4	3	2	1	0
COMM	DATA	PEC	Not Used			OTH	Not Used
R	R	R	R			R	R

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

**Table 21. STATUS\_CML**

Bit	Field	Type	Reset	Description
7	COMM	R	N/A	0: A valid or supported command has been received 1: An invalid or unsupported command has been received
6	DATA	R	N/A	0: A valid or supported data has been received 1: An invalid or unsupported data has been received
5	PEC	R	N/A	0: Packet Error Check has failed 1: Packet Error Check has succeeded
4:2	Not Used	R	N/A	Not Used
1	OTH	R	N/A	0: A communication fault other than the ones listed in this table has not occurred 1: A communication fault other than the ones listed in this table has occurred. Currently, this bit is only set for too many data bytes
0	Not Used	R	N/A	Not Used

**7.5.4.17 MFR\_SPECIFIC\_00 (address = D0h)**
**Figure 45. MFR\_SPECIFIC\_00**

7	6	5	4	3	2	1	0
USER SCRATCH PAD							
R/W							

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

**Table 22. MFR\_SPECIFIC\_00**

Bit	Field	Type	Reset	Description
7:0	USER SCRATCH PAD	R/W	0	The MFR_SPECIFIC_00 is a user-accessible register dedicated as a user scratch pad.

### 7.5.4.18 MFR\_SPECIFIC\_01 (address = D1h)

**Figure 46. MFR\_SPECIFIC\_01**

7	6	5	4	3	2	1	0
0	0	PGD			POD		
R	R	R/W			R/W		

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

**Table 23. MFR\_SPECIFIC\_01**

Bit	Field	Type	Reset	Description
7:6		R	00b	The MFR_SPECIFIC_01 is a user-accessible register dedicated for configuring the PGOOD delay and Power-On Delay functions. (Refer to <a href="#">Table 24</a> and <a href="#">Table 25</a> )
5:3	PGD	R/W	010b	
2:0	POD	R/W	010b	

**Table 24. PGD[2:0]**

PGD[2]	PGD[1]	PGD[0]	PGOOD Delay
0	0	0	256 $\mu$ s
0	0	1	512 $\mu$ s
0	1	0	1.024 ms
0	1	1	2.048 ms
1	0	0	4.096 ms
1	0	1	8.192 ms
1	1	0	16.384 ms
1	1	1	131.072 ms

**Table 25. POD[2:0]**

POD[2]	POD[1]	POD[0]	Power-On Delay
0	0	0	256 $\mu$ s
0	0	1	512 $\mu$ s
0	1	0	1.024 ms
0	1	1	2.048 ms
1	0	0	4.096 ms
1	0	1	8.192 ms
1	1	0	16.384 ms
1	1	1	32.768 ms

### 7.5.4.19 MFR\_SPECIFIC\_02 (address = D2h)

The MFR\_SPECIFIC\_02 register allows the user to read the configuration of various pinstrap features and/or overwrite them. Note, that any overwritten values here are only good until the next power-on-reset; when all parameters will revert back to their pinstrap configurations.

**Figure 47. MFR\_SPECIFIC\_02**

7	6	5	4	3	2	1	0
TRK	SEQ	0	FORCESKIPSS	SST		HICLOFF	CM
R/W	R/W	R	R/W	R/W		R/W	R/W

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

**Table 26. MFR\_SPECIFIC\_02**

Bit	Field	Type	Reset	Description
7	TRK	R/W	P	This bit indicates whether the device is using internal or external reference voltage tracking. It will initially be loaded and reflect the value of the pinstrap; but, can also be overwritten by PMBus. 0: No tracking. The device will use internal reference voltage. 1: External tracking.
6	SEQ	R/W	P	This bit indicates whether the device is using internal or external soft-start ramp. It will initially be loaded and reflect the value of the pinstrap; but, can also be overwritten by PMBus. 0: No sequencing. The device will use the internal soft start ramp. 1: Sequencing
5		R	0	
4	FORCESKIPSS	R/W	1	This bit (when set) allows the user to force Soft-start to always use SKIP mode; regardless of the CM pinstrap. 0: CM bit controls whether to operate in SKIP or FCCM mode during and after soft start. 1: Soft start is forced to operate in SKIP mode, then CM bit controls the mode after soft start.
3:2	SST	R/W	P	These bits indicate the time the device takes to ramp the output voltage up to regulation (that is, soft-start). The field will initially be loaded and reflect the value of the pinstrap; but, can also be overwritten by PMBus. (Refer to <a href="#">Table 27</a> )
1	HICLOFF	R/W	P	This bit indicates the response the device will take upon an output under-voltage fault. There are two fault response options which are enforced by the analog circuits: Hiccup or Latch-off. The bit value will initially be loaded and reflect the value of the pinstrap; but, can also be overwritten by PMBus. 0: Hiccup after UVP fault. 1: Latch off after UVP fault.
0	CM	R/W	P	This bit indicates the conduction mode for the device. The bit value will initially be loaded and reflect the value of the pinstrap; but, can also be overwritten by PMBus. 0: SKIP 1: FCCM

**Table 27. SST**

SST[1]	SST[0]	Soft-start time
0	0	1 ms
0	1	2 ms
1	0	4 ms
1	1	8 ms

#### 7.5.4.20 MFR\_SPECIFIC\_03 (address = D3h)

The MFR\_SPECIFIC\_03 register allows the user to read the configuration of the DCAP pinstrap feature (and/or overwrite it); as well configure the Ramp Generator and the PWM switching frequency.

**Figure 48. MFR\_SPECIFIC\_03**

7	6	5	4	3	2	1	0
DCAP3	0	RCSP	0	FS			
R/W	R	R/W	R	R/W			

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

**Table 28. MFR\_SPECIFIC\_03 Field Descriptions**

Bit	Field	Type	Reset	Description
7	DCAP3	R/W	P	This bit allows the user to read/configure the device's internal DCAP-3 mode. It will initially be loaded and reflect the value of the pinstrap; but, can also be overwritten by PMBus. 0: Internal DCAP3 is disabled (ramp injection is off). 1: Internal DCAP3 is enabled (ramp injection is on)
6		R	0	
5:4	RCSP	R/W	P	These bits allow the user to read/configure the D-CAP3 ramp generator's resistor value selection. (Refer to <a href="#">Table 29</a> )
3		R	0	
2:0	FS	R/W	011b	These bits allow the user to read/configure the device's PWM switching frequency. (Refer to <a href="#">Table 30</a> )

**Table 29. RCSP**

RCSP[1]	RCSP[0]	Resistor Selection
0	0	Resistor ÷ 2
0	1	Resistor ÷ 1
1	0	Resistor × 2
1	1	Resistor × 3

**Table 30. FS**

FS[2]	FS[1]	FS[0]	Switching Frequency
0	0	0	315 kHz
0	0	1	425 kHz
0	1	0	550 kHz
0	1	1	650 KHz
1	0	0	825 KHz
1	0	1	900 KHz
1	1	0	1.025 KHz
1	1	1	1.225 MHz

### 7.5.4.21 MFR\_SPECIFIC\_04 (address = D4h)

The MFR\_SPECIFIC\_04 register allows the user to configure the D-CAP offset reduction and fixed offset correction.

**Figure 49. MFR\_SPECIFIC\_04**

7	6	5	4	3	2	1	0
DCAP3OffsetSel	DCAP3Offset[1:0]		0	0	0	0	0
R/W	R/W		R	R	R	R	R

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

**Table 31. MFR\_SPECIFIC\_04**

Bit	Field	Type	Reset	Description
7	DCAP3OffsetSel	R/W	1	This bit allows the user to read/configure the D-CAP loop's offset reduction scheme. 0: Select DCAP loop manual offset reduction circuit. 1: Select DCAP loop automatic offset reduction circuit.
6:5	DCAP3Offset	R/W	0	These bits allow the user to read/configure the D-CAP3 offset correction if and only if DCAP3OffsetSel = 0 (refer to <a href="#">Table 32</a> )
4:0		R	0	

**Table 32. DCAP3OFFSET**

DCAP3Offset[1]	DCAP3Offset[0]	Additional Offset Correction Voltage Added
0	0	0 mV
0	1	+ 2 mV
1	0	+ 4 mV
1	1	+ 6 mV

#### 7.5.4.22 MFR\_SPECIFIC\_06 (address = D6h)

The MFR\_SPECIFIC\_06 is a user-accessible register dedicated for configuring the VDD Under-voltage LockOut threshold.

**Figure 50. MFR\_SPECIFIC\_06**

7	6	5	4	3	2	1	0
0	0	0	0	0	VDDUVLO[2:0]		
R	R	R	R	R	R/W		

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

**Table 33. MFR\_SPECIFIC\_06**

Bit	Field	Type	Reset	Description
7:3		R	0	
2:0	VDDUVLO	R/W	101b	These bits allow the user to read/configure the device's VDD Under-voltage Lockout threshold. (Refer to <a href="#">Table 34</a> )

**Table 34. VDDUVLO**

VDDUVLO[2]	VDDUVLO[1]	VDDUVLO[0]	VDD UVLO threshold
0	X	X	10.2 volts
1	0	0	2.8 volts
1	0	1	4.25 volts
1	1	0	6 volts
1	1	1	8.1 volts

### 7.5.4.23 MFR\_SPECIFIC\_07 (address = D7h)

The MFR\_SPECIFIC\_07 is a user-accessible register dedicated for configuring the device's PGOOD threshold and external tracking options.

**Figure 51. MFR\_SPECIFIC\_07**

7	6	5	4	3	2	1	0
VPBAD	SPARE	0	TRKOPTION	VTRKIN[3:0]			
R/W	R/W	R	R/W	R/W			

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

**Table 35. MFR\_SPECIFIC\_07**

Bit	Field	Type	Reset	Description
7	VPBAD	R/W	1	This bit allows the user to read/configure the PGOOD high and low thresholds. 0: PGOOD high and low thresholds are +16% and -16%, respectively 1: PGOOD high and low thresholds are +20% and -32%, respectively
6	SPARE	R/W	0	This bit allows the user to read/configure an EEPROM backed SPARE bit and corresponding digital block output. 0: pSPARE = 0 1: pSPARE = 1
5		R	0	
4	TRKOPTION	R/W	0	This bit allows the user to read/control whether the external TRKIN is enabled by a 425 mV threshold, or not. 0: TRKIN voltage must be above 425mV (that is, TRKINOK = 1) before switcher can be enabled. 1: TRKIN voltage does <b>not</b> need to be above 425mV before switcher can be enabled.
3:0	VTRKIN	R/W	1111b	These bits allow the user to read/configure the device's final TRKIN target voltage for external tracking operation. (Refer to <a href="#">Table 36</a> )

**Table 36. VTRKIN**

VTRKIN[3]	VTRKIN[2]	VTRKIN[1]	VTRKIN[0]	Final TRKIN target voltage for external tracking operation
0	0	0	0	500 mV
0	0	0	1	550 mV
0	0	1	0	600 mV
0	0	1	1	650 mV
0	1	0	0	700 mV
0	1	0	1	750 mV
0	1	1	0	800 mV
0	1	1	1	850 mV
1	0	0	0	900 mV
1	0	0	1	950 mV
1	0	1	0	1.00 V
1	0	1	1	1.05 V
1	1	0	0	1.10 V
1	1	0	1	1.15 V
1	1	1	0	1.20 V
1	1	1	1	1.25 V

#### 7.5.4.24 MFR\_SPECIFIC\_44 (address = FCh)

The DEVICE\_CODE command returns a 12-bit unique identifier code for the device and a 4 bit device revision code. Device revisions codes should start at 0x0.

**Figure 52. MFR\_SPECIFIC\_44**

7	6	5	4	3	2	1	0	7	6	5	4	3	2	1	0
Identifier Code												Revision Code			
R	R	R	R	R	R	R	R	R	R	R	R	R	R	R	R

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

**Table 37. MFR\_SPECIFIC\_44**

Bit	Field	Type	Reset	Description
7:0	Identifier Code	R	02h	0000 0010 0000b – Device ID Code Identifier for TPS549D22.
7:4		R	0	
3:0	Revision Code	R	0	0000b - Revision Code (first silicon starts at 0)



## 8 Application and Implementation

---

### NOTE

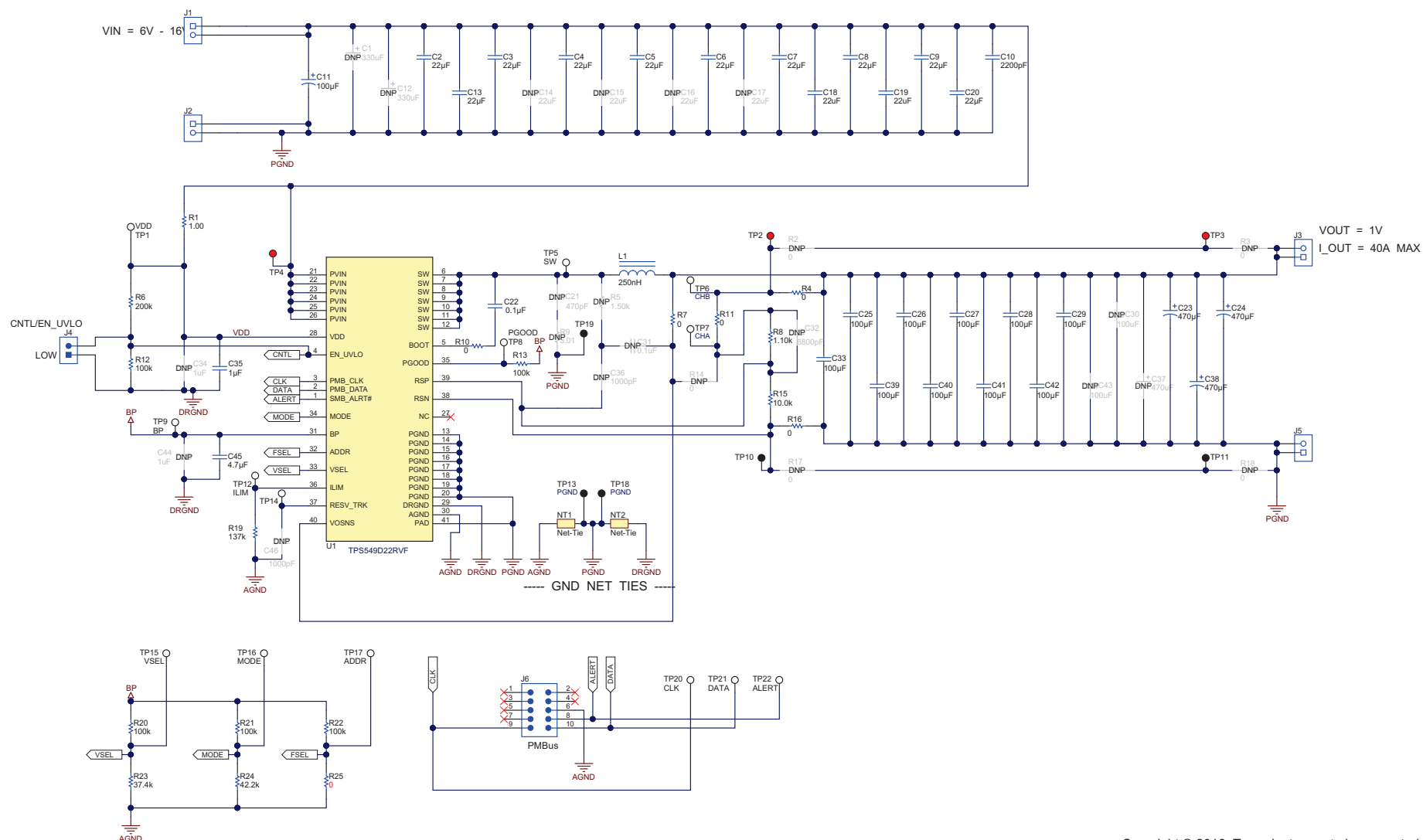
Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

---

### 8.1 Application Information

The TPS549D22 device is a highly-integrated synchronous step-down DC-DC converter with PMBus features and capabilities. This device is used to convert a higher DC input voltage to a lower DC output voltage, with a maximum output current of 40 A. Use the following design procedure to select key component values for this family of devices.

## 8.2 Typical Application: TPS549D22 1.5-V to 16-V Input, 1-V Output, 40-A Converter



Copyright © 2016, Texas Instruments Incorporated

Figure 53. Typical Application Schematic

## 8.2.1 Design Requirements

For this design example, use the input parameters shown in [Table 38](#).

**Table 38. Design Example Specifications**

PARAMETER	TEST CONDITION	MIN	TYP	MAX	UNIT
$V_{IN}$ Input voltage		5	12	16	V
$V_{IN(ripple)}$ Input ripple voltage	$I_{OUT} = 40\text{ A}$			0.4	V
$V_{OUT}$ Output voltage			1		V
Line regulation	$5\text{ V} \leq V_{IN} \leq 16\text{ V}$			0.5%	
Load regulation	$0\text{ V} \leq I_{OUT} \leq 40\text{ A}$			0.5%	
$V_{PP}$ Output ripple voltage	$I_{OUT} = 40\text{ A}$		20		mV
$V_{OVER}$ Transient response overshoot	$I_{STEP} = 24\text{ A}$		90		mV
$V_{UNDER}$ Transient response undershoot	$I_{STEP} = 24\text{ A}$		90		mV
$I_{OUT}$ Output current	$5\text{ V} \leq V_{IN} \leq 16\text{ V}$			40	A
$t_{SS}$ Soft-start time	$V_{IN} = 12\text{ V}$		1		ms
$I_{OC}$ Overcurrent trip point <sup>(1)</sup>			46		A
$\eta$ Peak Efficiency	$I_{OUT} = 20\text{ A}$ , $V_{IN} = 12\text{ V}$ , $V_{DD} = 5\text{ V}$		90%		
$f_{SW}$ Switching frequency			650		kHz

(1) DC overcurrent level

## 8.2.2 Detailed Design Procedure

### 8.2.2.1 Custom Design With WEBENCH® Tools

[Click here](#) to create a custom design using the TPS549D22 device with the WEBENCH® Power Designer.

1. Start by entering the input voltage ( $V_{IN}$ ), output voltage ( $V_{OUT}$ ), and output current ( $I_{OUT}$ ) requirements.
2. Optimize the design for key parameters such as efficiency, footprint, and cost using the optimizer dial.
3. Compare the generated design with other possible solutions from Texas Instruments.

The WEBENCH Power Designer provides a customized schematic along with a list of materials with real-time pricing and component availability.

In most cases, these actions are available:

- Run electrical simulations to see important waveforms and circuit performance
- Run thermal simulations to understand board thermal performance
- Export customized schematic and layout into popular CAD formats
- Print PDF reports for the design, and share the design with colleagues

Get more information about WEBENCH tools at [www.ti.com/WEBENCH](http://www.ti.com/WEBENCH).

### 8.2.2.2 Switching Frequency Selection

The default switching frequency of the TPS549D22 device is 650 kHz. There are a total of 8 switching frequency settings that can be programmed via PMBus interface. For each switching frequency setting, there are 4 internal ramp compensations (DCAP3) to choose from, also via PMBus. When DCAP3 mode is selected (preferred), the internal ramp compensation is used for stabilizing the converter design. The ramp is a function of the switching frequency and duty cycle range (the output voltage to input voltage ratio). [Table 39](#) summarizes the ramp choices using these functions.

**Table 39. Switching Frequency Selection**

SWITCHING FREQUENCY SETTING (f <sub>sw</sub> ) (kHz)	RAMP SELECT OPTION	TIME CONSTANT t (μs)	V <sub>OUT</sub> RANGE (FIXED V <sub>IN</sub> = 12 V)		DUTY CYCLE RANGE (V <sub>OUT</sub> /V <sub>IN</sub> ) (%)	
			MIN	MAX	MIN	MAX
315, 425	R/2	9	0.6	0.9	5	7.5
	R × 1	16.8	0.9	1.5	7.5	12.5
	R × 2	32.3	1.5	2.5	12.5	21
	R × 3	55.6	2.5	5.5	>21	
550, 650	R/2	7	0.6	0.9	5	7.5
	R × 1	13.5	0.9	1.5	7.5	12.5
	R × 2	25.9	1.5	2.5	12.5	21
	R × 3	44.5	2.5	5.5	>21	
825, 900	R/2	5.6	0.6	0.9	5	7.5
	R × 1	10.4	0.9	1.5	7.5	12.5
	R × 2	20	1.5	2.5	12.5	21
	R × 3	34.4	2.5	5.5	>21	
1.025, 1.225 MHz	R/2	3.8	0.6	0.9	5	7.5
	R × 1	7.1	0.9	1.5	7.5	12.5
	R × 2	13.6	1.5	2.5	12.5	21
	R × 3	23.3	2.5	5.5	>21	

### 8.2.2.3 Inductor Selection

To calculate the value of the output inductor, use [Equation 3](#). The coefficient K<sub>IND</sub> represents the amount of inductor ripple current relative to the maximum output current. The output capacitor filters the inductor ripple current. Therefore, choosing a high inductor ripple current impacts the selection of the output capacitor since the output capacitor must have a ripple current rating equal to or greater than the inductor ripple current. In general, maintain a K<sub>IND</sub> coefficient between 0 and 15 for balanced performance. Using this target ripple current, the required inductor size can be calculated as shown in [Equation 3](#)

$$L_1 = \frac{V_{OUT}}{(V_{IN(max)} \times f_{SW})} \times \frac{V_{IN} - V_{OUT}}{(I_{OUT(max)} \times K_{IND})} = \frac{1 \text{ V} \times (16 \text{ V} - 1 \text{ V})}{(16 \text{ V} \times 650 \text{ kHz} \times 40 \text{ A} \times 0.15)} = 0.24 \mu\text{H} \quad (3)$$

Selecting a K<sub>IND</sub> of 0.15, the target inductance L<sub>1</sub> = 250 nH. Using the next standard value, the 250 nH is chosen in this application for its high current rating, low DCR, and small size. The inductor ripple current, RMS current, and peak current can be calculated using [Equation 4](#), [Equation 5](#) and [Equation 6](#). These values should be used to select an inductor with approximately the target inductance value, and current ratings that allow normal operation with some margin.

$$I_{RIPPLE} = \frac{V_{OUT}}{(V_{IN(max)} \times f_{SW})} \times \frac{V_{IN(max)} - V_{OUT}}{L_1} = \frac{1 \text{ V} \times (16 \text{ V} - 1 \text{ V})}{16 \text{ V} \times 650 \text{ kHz} \times 250 \text{ nH}} = 5.64 \text{ A} \quad (4)$$

$$I_{L(rms)} = \sqrt{(I_{OUT})^2 + \frac{1}{12} \times (I_{RIPPLE})^2} = 40 \text{ A} \quad (5)$$

$$I_{L(peak)} = (I_{OUT}) + \frac{1}{2} \times (I_{RIPPLE}) = 43 \text{ A} \quad (6)$$

The Würth ferrite 744309025 inductor is rated for 50 A<sub>RMS</sub> current, and 48-A saturation. Using this inductor, the ripple current I<sub>RIPPLE</sub> = 5.64 A, the RMS inductor current I<sub>L(rms)</sub> = 40 A, and peak inductor current I<sub>L(peak)</sub> = 43 A.

### 8.2.2.4 Output Capacitor Selection

There are three primary considerations for selecting the value of the output capacitor. The output capacitor affects three criteria:

- Stability

- Regulator response to a change in load current or load transient
- Output voltage ripple

These three considerations are important when designing regulators that must operate where the electrical conditions are unpredictable. The output capacitance needs to be selected based on the most stringent of these three criteria.

#### 8.2.2.4.1 Minimum Output Capacitance to Ensure Stability

To prevent sub-harmonic multiple pulsing behavior, TPS549D22 application designs must strictly follow the small signal stability considerations described in [Equation 7](#).

$$C_{OUT(min)} > \frac{t_{ON}}{2} \times \frac{8\tau}{L_{OUT}} \times \frac{V_{REF}}{V_{OUT}}$$

where

- $C_{OUT(min)}$  is the minimum output capacitance needed to meet the stability requirement of the design
- $t_{ON}$  is the on-time information based on the switching frequency and duty cycle (in this design, 133 ns)
- $\tau$  is the ramp compensation time constant of the design based on the switching frequency and duty cycle, (in this design, 13.45  $\mu$ s, refer to [Table 39](#))
- $L_{OUT}$  is the output inductance (in the design, 0.25  $\mu$ H)
- $V_{REF}$  is the user-selected reference voltage level (in this design, 1 V)
- $V_{OUT}$  is the output voltage (in this design, 1 V)

(7)

The minimum output capacitance calculated from [Equation 7](#) is 28.6  $\mu$ F. The stability is ensured when the amount of the output capacitance is 28.6  $\mu$ F or greater. And when all MLCCs (multi-layer ceramic capacitors) are used, both DC and AC derating effects must be considered to ensure that the minimum output capacitance requirement is met with sufficient margin.

#### 8.2.2.4.2 Response to a Load Transient

The output capacitance must supply the load with the required current when current is not immediately provided by the regulator. When the output capacitor supplies load current, the impedance of the capacitor greatly affects the magnitude of voltage deviation (such as undershoot and overshoot) during the transient.

Use [Equation 8](#) and [Equation 9](#) to estimate the amount of capacitance needed for a given dynamic load step and release.

#### NOTE

There are other factors that can impact the amount of output capacitance for a specific design, such as ripple and stability.

$$C_{OUT(min\_under)} = \frac{L_{OUT} \times (\Delta I_{LOAD(max)})^2 \times \left( \frac{V_{OUT} \times t_{SW}}{V_{IN(min)}} + t_{OFF(min)} \right)}{2 \times \Delta V_{LOAD(insert)} \times \left( \left( \frac{V_{IN(min)} - V_{OUT}}{V_{IN(min)}} \right) \times t_{SW} - t_{OFF(min)} \right) \times V_{OUT}}$$

(8)

$$C_{OUT(min\_over)} = \frac{L_{OUT} \times (\Delta I_{LOAD(max)})^2}{2 \times \Delta V_{LOAD(release)} \times V_{OUT}}$$

where

- $C_{OUT(min\_under)}$  is the minimum output capacitance to meet the undershoot requirement
- $C_{OUT(min\_over)}$  is the minimum output capacitance to meet the overshoot requirement
- $L$  is the output inductance value (0.25  $\mu$ H)
- $\Delta I_{LOAD(max)}$  is the maximum transient step (24 A)
- $V_{OUT}$  is the output voltage value (1 V)
- $t_{SW}$  is the switching period (1.538  $\mu$ s)
- $V_{IN(min)}$  is the minimum input voltage for the design (10.8 V)
- $t_{OFF(min)}$  is the minimum off time of the device (300 ns)
- $\Delta V_{LOAD(insert)}$  is the undershoot requirement (30 mV)
- $\Delta V_{LOAD(release)}$  is the overshoot requirement (30 mV)

(9)

Most of the above parameters can be found in [Table 38](#).

The minimum output capacitance to meet the undershoot requirement is 969  $\mu$ F. The minimum output capacitance to meet the overshoot requirement is 2400  $\mu$ F. This example uses a combination of POSCAP and MLCC capacitors to meet the overshoot requirement.

- POSCAP bank #1: 4 x 470  $\mu$ F, 2.5 V, 6 m $\Omega$  per capacitor
- MLCC bank #2: 10 x 100  $\mu$ F, 2.5 V, 1 m $\Omega$  per capacitor with DC+AC derating factor of 60%

Recalculating the worst case overshoot using the described capacitor bank design, the overshoot is 29.0 mV which meets the 30 mV overshoot specification requirement.

#### 8.2.2.4.3 Output Voltage Ripple

The output voltage ripple is another important design consideration. [Equation 10](#) calculates the minimum output capacitance required to meet the output voltage ripple specification. This criterion is the requirement when the impedance of the output capacitance is dominated by ESR.

$$C_{OUT(min)RIPPLE} = \frac{I_{RIPPLE}}{8 \times f_{SW} \times V_{OUT(ripple)}} = 108 \mu F$$

(10)

In this case, the maximum output voltage ripple is 10 mV. For this requirement, the minimum capacitance for ripple requirement yields 108  $\mu$ F. Because this capacitance value is significantly lower compared to that of transient requirement, determine the capacitance bank from steps in the previous section [Response to a Load Transient](#). Because the output capacitor bank consists of both POSCAP and MLCC type capacitors, it is important to consider the ripple effect at the switching frequency due to effective ESR. Use [Equation 11](#) to determine the maximum ESR of the output capacitor bank for the switching frequency.

$$ESR_{MAX} = \frac{V_{OUT(ripple)} - \frac{I_{RIPPLE}}{8 \times f_{SW} \times C_{OUT}}}{I_{RIPPLE}} = 1.7 m\Omega$$

(11)

Estimate the effective ESR at the switching frequency by obtaining the impedance vs. frequency characteristics of the output capacitors. The parallel impedance of capacitor bank #1 and capacitor bank #2 at the switching frequency of the design example is estimated to be 1.2 m $\Omega$ , which is less than that of the maximum ESR value. Therefore, the output voltage ripple requirement (7 mV) can be met. For detailed calculation on the effective ESR please contact the factory to obtain a user-friendly Excel based design tool.

### 8.2.2.5 Input Capacitor Selection

The TPS549D22 devices require a high-quality, ceramic, type X5R or X7R, input decoupling capacitor with a value of at least 1  $\mu\text{F}$  of effective capacitance on the VDD pin, relative to AGND. The power stage input decoupling capacitance (effective capacitance at the PVIN and PGND pins) must be sufficient to supply the high switching currents demanded when the high-side MOSFET switches on, while providing minimal input voltage ripple as a result. This effective capacitance includes any DC bias effects. The voltage rating of the input capacitor must be greater than the maximum input voltage. The capacitor must also have a ripple current rating greater than the maximum input current ripple to the device during full load. The input ripple current can be calculated using Equation 12.

$$I_{\text{CIN (rms)}} = I_{\text{OUT (max)}} \times \sqrt{\frac{V_{\text{OUT}}}{V_{\text{IN (min)}}} \times \frac{(V_{\text{IN (min)}} - V_{\text{OUT}})}{V_{\text{IN (min)}}}} = 16 \text{ Arms} \quad (12)$$

The minimum input capacitance and ESR values for a given input voltage ripple specification,  $V_{\text{IN(ripple)}}$ , are shown in Equation 13 and Equation 14. The input ripple is composed of a capacitive portion,  $V_{\text{RIPPLE(cap)}}$ , and a resistive portion,  $V_{\text{RIPPLE(esr)}}$ .

$$C_{\text{IN (min)}} = \frac{I_{\text{OUT (max)}} \times V_{\text{OUT}}}{V_{\text{RIPPLE (cap)}} \times V_{\text{IN (max)}} \times f_{\text{SW}}} = 38.5 \mu\text{F} \quad (13)$$

$$\text{ESR}_{\text{CIN (max)}} = \frac{V_{\text{RIPPLE(ESR)}}}{I_{\text{OUT (max)}} + \left(\frac{I_{\text{RIPPLE}}}{2}\right)} = 7 \text{ m}\Omega \quad (14)$$

The value of a ceramic capacitor varies significantly over temperature and the amount of DC bias applied to the capacitor. The capacitance variations due to temperature can be minimized by selecting a dielectric material that is stable over temperature. X5R and X7R ceramic dielectrics are usually selected for power regulator capacitors because they have a high capacitance to volume ratio and are fairly stable over temperature. The input capacitor must also be selected with the DC bias taken into account. For this example design, a ceramic capacitor with at least a 25-V voltage rating is required to support the maximum input voltage. For this design, allow 0.1-V input ripple for  $V_{\text{RIPPLE(cap)}}$ , and 0.3-V input ripple for  $V_{\text{RIPPLE(esr)}}$ . Using Equation 13 and Equation 14, the minimum input capacitance for this design is 38.5  $\mu\text{F}$ , and the maximum ESR is 9.4 m $\Omega$ . For this example, four 22- $\mu\text{F}$ , 25-V ceramic capacitors and one additional 100- $\mu\text{F}$ , 25-V low-ESR polymer capacitors in parallel were selected for the power stage.

### 8.2.2.6 Bootstrap Capacitor Selection

A ceramic capacitor with a value of 0.1  $\mu\text{F}$  must be connected between the BOOT and SW pins for proper operation. It is recommended to use a ceramic capacitor with X5R or better grade dielectric. Use a capacitor with a voltage rating of 25 V or higher.

### 8.2.2.7 BP Pin

Bypass the BP pin to DRGND with 4.7- $\mu\text{F}$  of capacitance. In order for the regulator to function properly, it is important that these capacitors be localized to the TPS549D22, with low-impedance return paths. See [Layout Guidelines](#) section for more information.

### 8.2.2.8 R-C Snubber and VIN Pin High-Frequency Bypass

Though it is possible to operate the TPS549D22 within absolute maximum ratings without ringing reduction techniques, some designs may require external components to further reduce ringing levels. This example uses two approaches: a high frequency power stage bypass capacitor on the VIN pins, and an R-C snubber between the SW area and GND.

The high-frequency VIN bypass capacitor is a lossless ringing reduction technique which helps minimizes the outboard parasitic inductances in the power stage, which store energy during the low-side MOSFET on-time, and discharge once the high-side MOSFET is turned on. For this example two 2.2-nF, 25-V, 0603-sized high-frequency capacitors are used. The placement of these capacitors is critical to its effectiveness. Its ideal placement is shown in .



Additionally, an R-C snubber circuit is added to this example. To balance efficiency and spike levels, a 1-nF capacitor and a 1-Ω resistor are chosen. In this example a 0805-sized resistor is chosen, which is rated for 0.125 W, nearly twice the estimated power dissipation. See [SLUP100](#) for more information about snubber circuits.

### 8.2.2.9 Optimize Reference Voltage (VSEL)

Optimize the reference voltage by choosing a value for  $R_{VSEL}$ . The TPS549D22 device is designed with a wide range of precision reference voltage support from 0.6 V to 1.2 V with an available step change of 50 mV. Program these reference voltages using the VSEL pin strap configurations. See [Table 2](#) for internal reference voltage selections. In addition to providing initial boot voltage value, use the VSEL pin to program hiccup and latch-off mode.

There are two ways to program the output voltage set point. If the output voltage setpoint is one of the 16 available reference and boot voltage options, no feedback resistors are required for output voltage programming. In the case where feedback resistors are not needed, connect the RSP pin to the positive sensing point of the load. Always connect the RSN pin to the load return sensing point.

In this design example, because the output voltage set point is 1 V, select  $R_{VSEL(LS)}$  of either 75 kΩ (latch off) or 68.1 kΩ (hiccup) as shown in [Table 3](#). If the output voltage set point is NOT one of the 16 available reference or boot voltage options, feedback resistors are required for output voltage programming. Connect the RSP pin to the mid-point of the resistor divider. Always connect the RSN pin to the load return sensing point as shown in [and](#).

The general guideline to select boot and internal reference voltage is to select the reference voltage closest to the output voltage setpoint. In addition, because the RSP and RSN pins are extremely high-impedance input terminals of the true differential remote sense amplifier, use a feedback resistor divider with values much less than 100 kΩ.

### 8.2.2.10 MODE Pin Selection

MODE pin strap configuration is used to program control topology and internal soft-start timing selections. TPS549D22 supports both DCAP3 and DCAP operation. For general POL applications, it is strongly recommended to configure the control topology to be DCAP3 due to its simple to use and no external compensation features. In the rare instance where DCAP is needed, an RCC network across the output inductor is needed to generate sufficient ripple voltage on the RSP pin. In this design example,  $R_{MODE(LS)}$  of 42.2 kΩ is selected for DCAP3 and soft start time of 1 ms.

### 8.2.2.11 ADDR Pin Selection

ADDR pin strap configuration is used to program device address and light load conduction mode selection. The TPS549D22 allows up to 16 different chip addresses for PMBus communication with the first 3 bits fixed as 001. The address selection process is defined by resistor divider ratio from BP pin to ADDR pin, and the address detection circuit will start to work only after the initial power up when VDD has risen above its UVLO threshold.

For this application example, a device address of 16d is desired. We select the low side RADDR to be 0 Ohm considering the SKIP operation and device address of 16d. [Table 4](#) lists all combinations of the address selections. The 1% or better tolerance resistors with typical temperature coefficient of ±100ppm/°C are recommended

### 8.2.2.12 Overcurrent Limit Design

The TPS549D22 device uses the ILIM pin to set the OCP level. Connect the ILIM pin to GND through the voltage setting resistor,  $R_{ILIM}$ . In order to provide both good accuracy and cost effective solution, this device supports temperature compensated MOSFET on-resistance ( $R_{DS(on)}$ ) sensing. Also, this device performs both positive and negative inductor current limiting with the same magnitudes. Positive current limit is normally used to protect the inductor from saturation therefore causing damage to the high-side and low-side FETs. Negative current limit is used to protect the low-side FET during OVP discharge.

The inductor current is monitored by the voltage between PGND pin and SW pin during the OFF time. The ILIM pin has 3000 ppm/°C temperature slope to compensate the temperature dependency of the on-resistance. The PGND pin is used as the positive current sensing node.



TPS549D22 has cycle-by-cycle over-current limiting control. The inductor current is monitored during the OFF state and the controller maintains the OFF state during the period that the inductor current is larger than the overcurrent ILIM level. The voltage on the ILIM pin (V<sub>ILIM</sub>) sets the valley level of the inductor current. The range of value of the R<sub>ILIM</sub> resistor is between 21 kΩ and 237 kΩ. The range of valley OCL is between 6.25 A and 75 A (typical). If the R<sub>ILIM</sub> resistance is outside of the recommended range, OCL accuracy and function cannot be ensured. (see [Table 40](#))

**Table 40. Closed Loop EVM Measurement of OCP Settings**

R <sub>ILIM</sub> (kΩ)	OVERCURRENT PROTECTION VALLEY (A)		
	MIN	NOM	MAX
237	—	75	—
127	36	40	44
95.3	27	30	33
63.4	18	20	22
32.4	9	10	11
21	—	6.25	—

Use [Equation 15](#) to relate the valley OCL to the R<sub>ILIM</sub> resistance.

$$OCL_{VALLEY} = 0.3178 \times R_{ILIM} - 0.3046$$

where

- R<sub>ILIM</sub> is in kΩ
  - OCL<sub>VALLEY</sub> is in A
- (15)

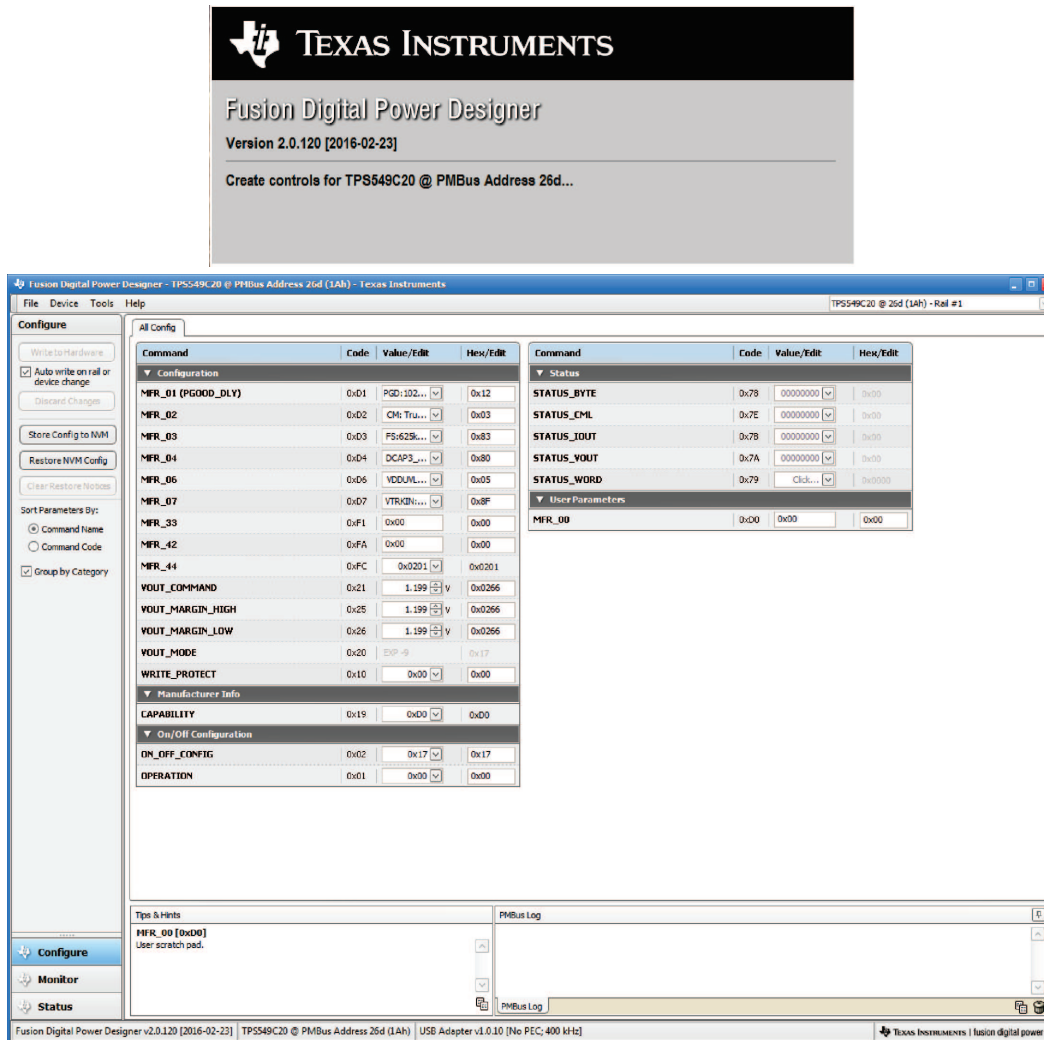
In this design example, the desired valley OCL is 43 A, the calculated R<sub>ILIM</sub> is 137 kΩ. Use [Equation 16](#) to calculate the DC OCL to be 46 A.

$$OCL_{DC} = OCL_{VALLEY} + 0.5 \times I_{RIPPLE}$$

where

- R<sub>ILIM</sub> is in kΩ
  - OCL<sub>DC</sub> is in A
- (16)

In an overcurrent condition, the current to the load exceeds the inductor current and the output voltage falls. When the output voltage crosses the under-voltage fault threshold for at least 1msec, the behavior of the device depends on the VSEL pin strap setting. If hiccup mode is selected, the device will restart after 16-ms delay (1-ms soft-start option). If the overcurrent condition persists, the OC hiccup behavior repeats. During latch-off mode operation the device shuts down until the EN pin is toggled or VDD pin is power cycled.



**Figure 54. VOUT Command Graphic User Interface**

## 8.2.3 Application Curves

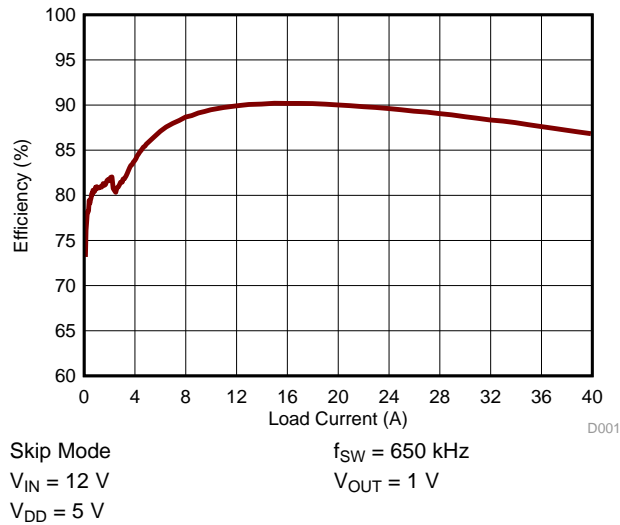


Figure 55. Efficiency vs. Load Current

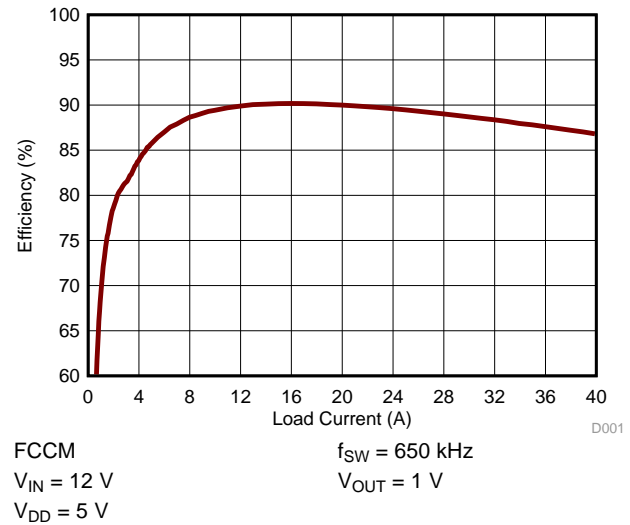


Figure 56. Efficiency vs. Load Current

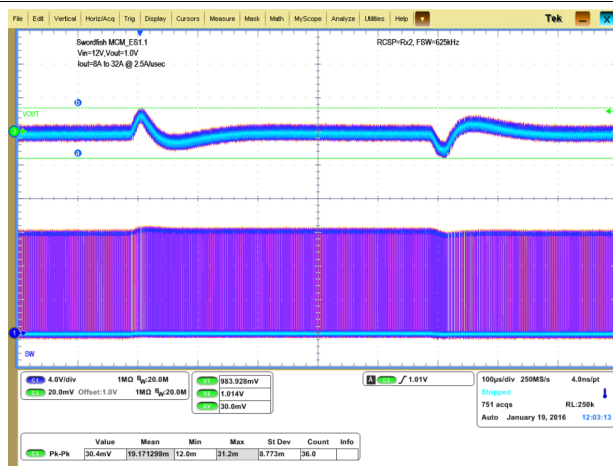


Figure 57. Transient Response Peak-to-Peak

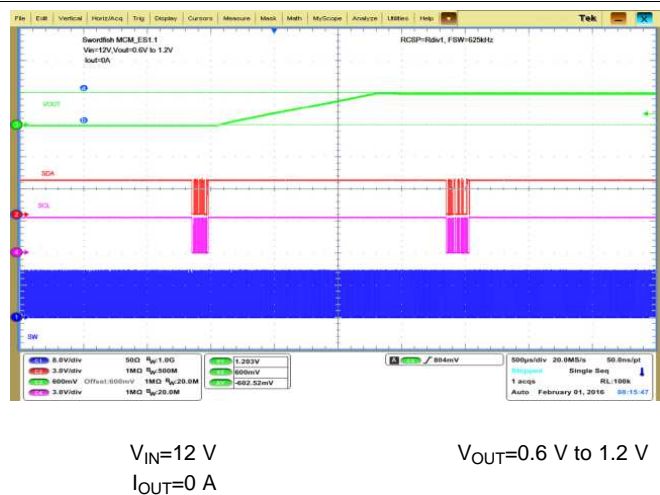


Figure 58. VOUT Command: 0.6 V to 1.2 V, IOUT = 0 A

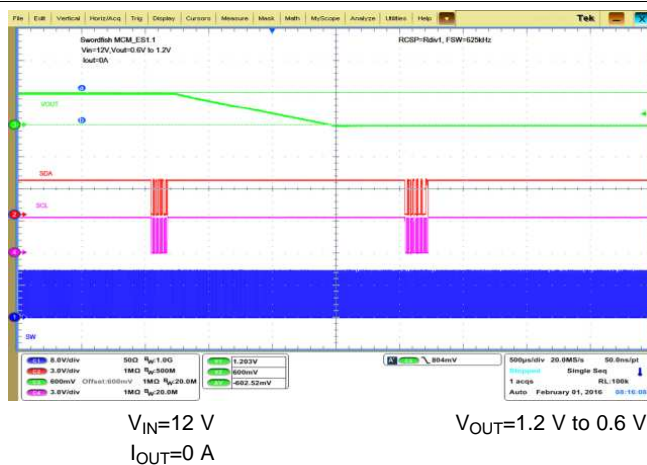


Figure 59. VOUT Command: 1.2 V to 0.6 V, IOUT = 0 A

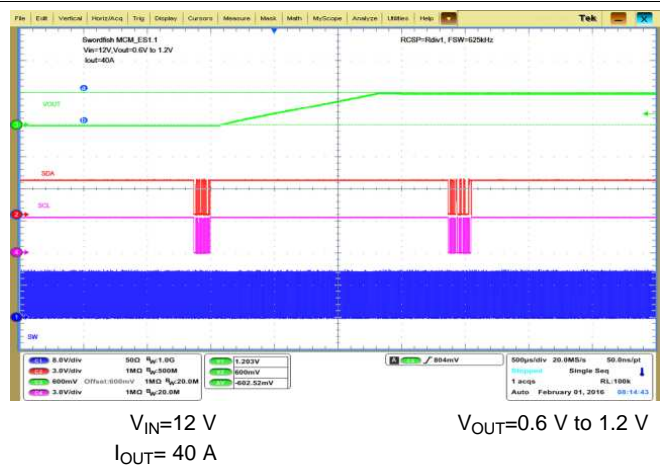
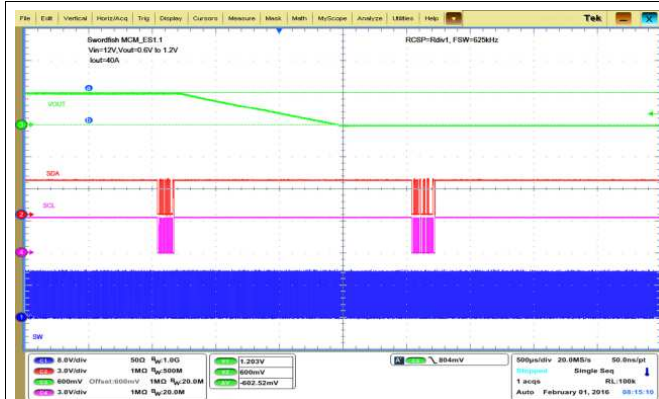


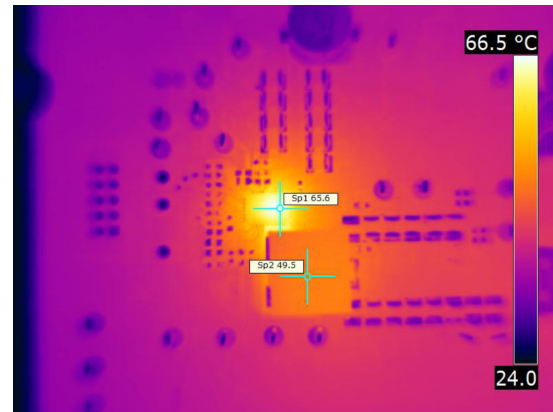
Figure 60. VOUT Command: 0.6 V to 1.2 V, IOUT = 40 A



$V_{IN}=12\text{ V}$   
 $I_{OUT}=40\text{ A}$

 $V_{OUT}=1.2\text{ V to }0.6\text{ V}$ 
$$I_{OUT}=40 \text{ A}$$

**Figure 61. VOUT Command: 1.2 V to 0.6 V, IO<sub>UT</sub> = 40 A**


$$V_{IN} = 12 \text{ V}$$
$$V_{OUT} = 1 \text{ V}$$

$f_{SW} = 650 \text{ kHz}$   
Airflow = 200 LFM

$$I_{OUT} = 40 \text{ A}$$

**Figure 62. Thermal Image**

## 9 Power Supply Recommendations

This device is designed to operate from an input voltage supply between 1.5 V and 16 V. Ensure the supply is well regulated. Proper bypassing of input supplies and internal regulators is also critical for noise performance, as is the quality of the PCB layout and grounding scheme. See the recommendations in the [Layout](#) section.

## 10 Layout

### 10.1 Layout Guidelines

Consider these layout guidelines before starting a layout work using TPS549D22.

- It is absolutely critical that all GND pins, including AGND (pin 30), DRGND (pin 29), and PGND (pins 13, 14, 15, 16, 17, 18, 19, and 20) are connected directly to the thermal pad underneath the device via traces or plane.
- Include as many thermal vias as possible to support a 40-A thermal operation. For example, a total of 35 thermal vias are used (outer diameter of 20 mil) in the available for purchase at ti.com.
- Place the power components (including input/output capacitors, output inductor and device) on one side of the PCB (solder side). Insert at least two inner layers (or planes) connected to the power ground, in order to shield and isolate the small signal traces from noisy power lines.
- Place the VIN pin decoupling capacitors as close as possible to the PVIN and PGND pins to minimize the input AC current loop. Place a high-frequency decoupling capacitor (with a value between 1 nF and 0.1  $\mu$ F) as close to the PVIN pin and PGND pin as the spacing rule allows. This placement helps suppress the switch node ringing.
- Place VDD and BP decoupling capacitors as close to the device pins as possible. Do not use PVIN plane connection for the VDD pin. Separate the VDD signal from the PVIN signal by using separate trace connections. Provide GND vias for each decoupling capacitor and make the loop as small as possible.
- Ensure that the PCB trace defined as switch node (which connects the SW pins and up-stream of the output inductor) are as short and wide as possible. In the EVM design, the SW trace width is 200 mil. Use a separate via or trace to connect SW node to snubber and bootstrap capacitor. Do not combine these connections.
- Place all sensitive analog traces and components (including VOSNS, RSP, RSN, ILIM, MODE, VSEL and ADDR) far away from any high voltage switch node (itself and others), such as SW and BOOT to avoid noise coupling. In addition, place MODE, VSEL and ADDR programming resistors near the device pins.
- The RSP and RSN pins operate as inputs to a differential remote sense amplifier that operates with very high impedance. It is essential to route the RSP and RSN pins as a pair of diff-traces in Kelvin-sense fashion. Route them directly to either the load sense points (+ and –) or the output bulk capacitors. The internal circuit uses the VOSNS pin for on-time adjustment. It is critical to tie the VOSNS pin directly tied to VOUT (load sense point) for accurate output voltage result.

## 10.2 Layout Example

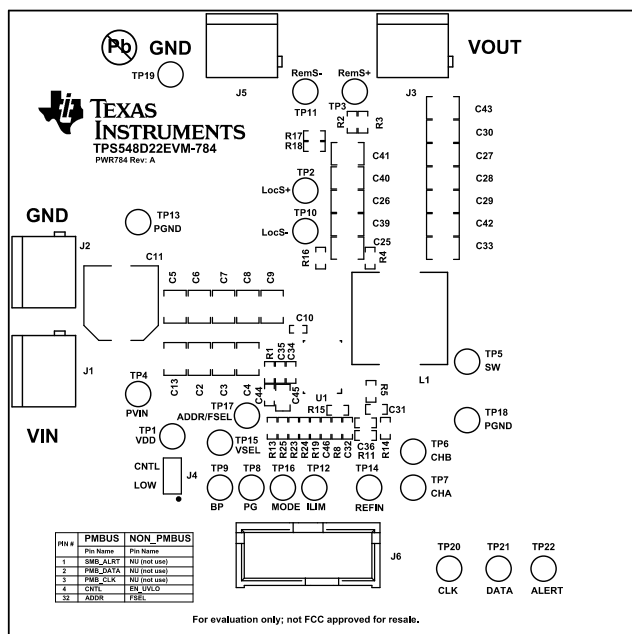


Figure 63. EVM Top View

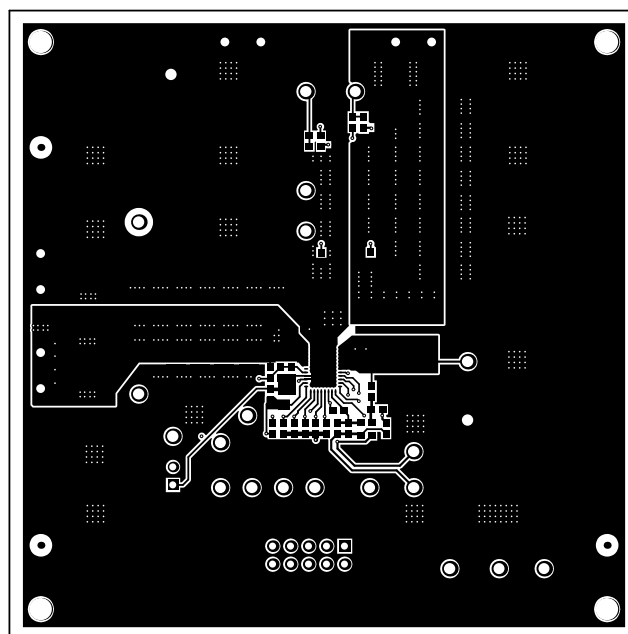


Figure 64. EVM Top Layer

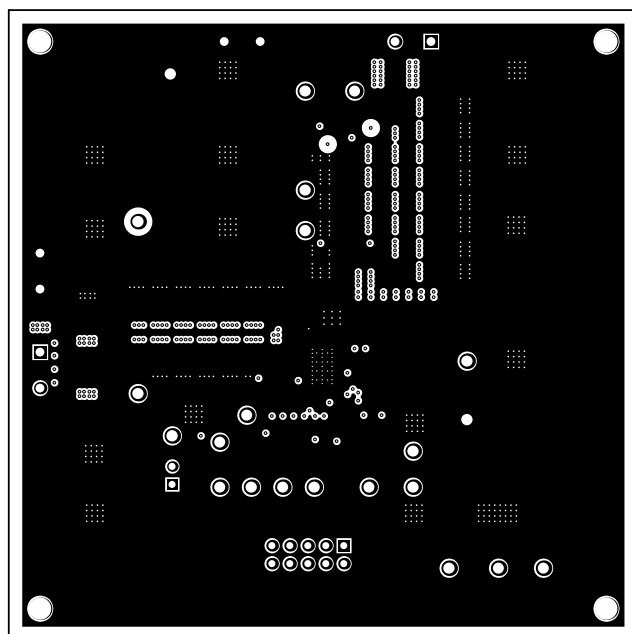


Figure 65. EVM Inner Layer 1

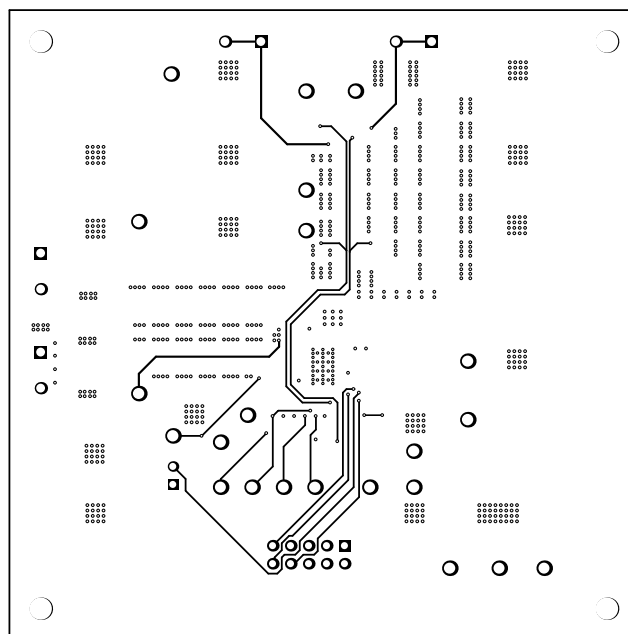
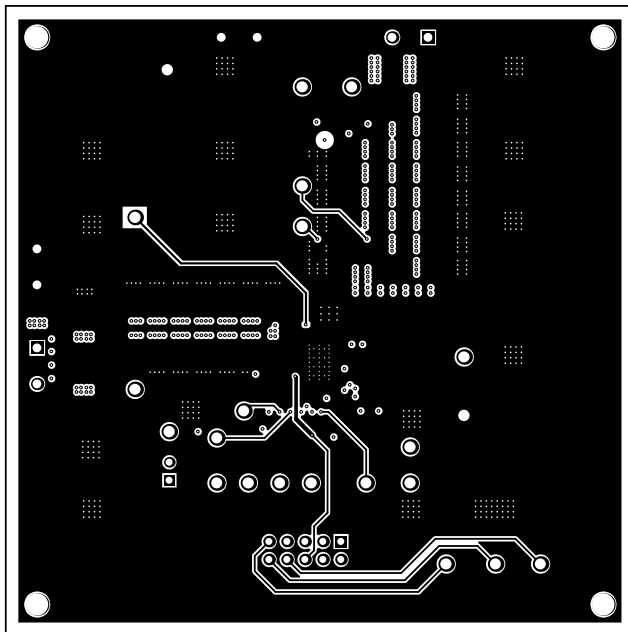
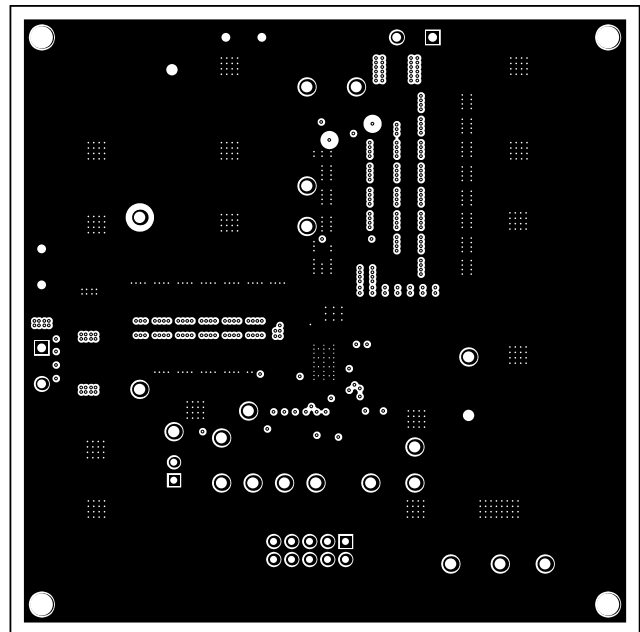
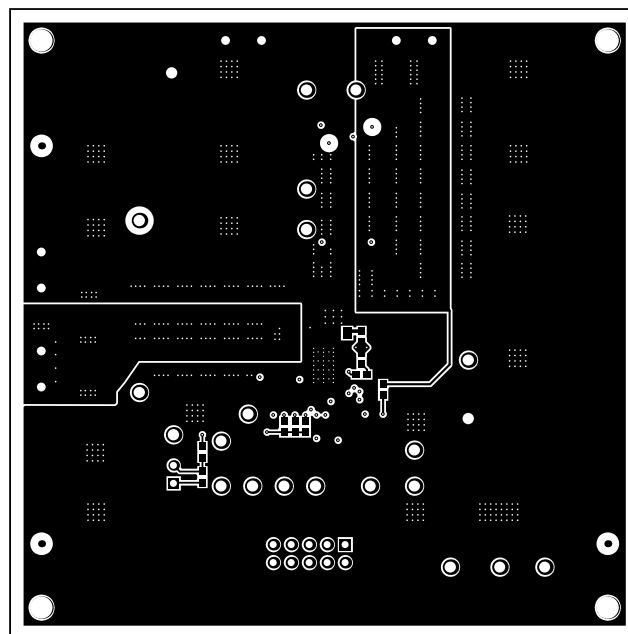


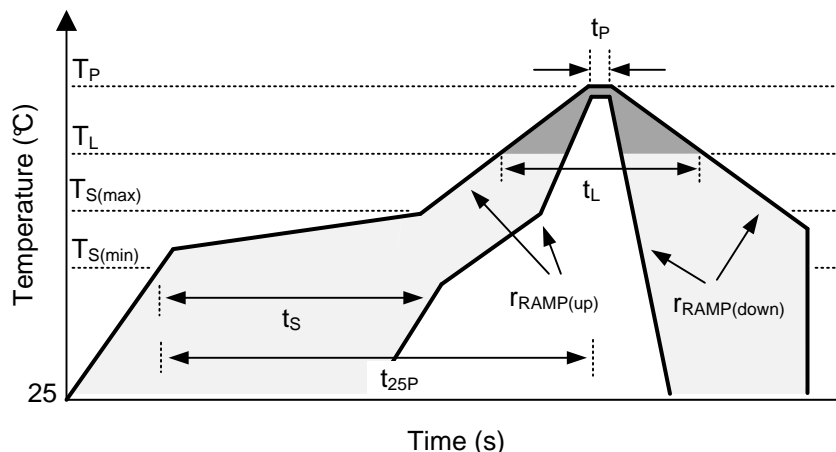
Figure 66. EVM Inner Layer 2

**Layout Example (continued)**

**Figure 67. EVM Inner Layer 3**

**Figure 68. EVM Inner Layer 4**

**Figure 69. EVM Bottom Layer**

## Layout Example (continued)

### 10.2.1 Mounting and Thermal Profile Recommendation

Proper mounting technique adequately covers the exposed thermal tab with solder. Excessive heat during the reflow process can affect electrical performance. [Figure 70](#) shows the recommended reflow oven thermal profile. Proper post-assembly cleaning is also critical to device performance. See the Application Report, *QFN/SON PCB Attachment*, ([SLUA271](#)) for more information.



**Figure 70. Recommended Reflow Oven Thermal Profile**

**Table 41. Recommended Thermal Profile Parameters**

PARAMETER		MIN	TYP	MAX	UNIT
<b>RAMP UP AND RAMP DOWN</b>					
$r_{\text{RAMP(up)}}$	Average ramp-up rate, $T_{\text{S(max)}}$ to $T_{\text{P}}$			3	°C/s
$r_{\text{RAMP(down)}}$	Average ramp-down rate, $T_{\text{P}}$ to $T_{\text{S(max)}}$			6	°C/s
<b>PRE-HEAT</b>					
$T_{\text{S}}$	Pre-heat temperature	150		200	°C
$t_{\text{S}}$	Pre-heat time, $T_{\text{S(min)}}$ to $T_{\text{S(max)}}$	60		180	s
<b>REFLOW</b>					
$T_{\text{L}}$	Liquidus temperature		217		°C
$T_{\text{P}}$	Peak temperature			260	°C
$t_{\text{L}}$	Time maintained above liquidus temperature, $T_{\text{L}}$	60		150	s
$t_{\text{P}}$	Time maintained within 5°C of peak temperature, $T_{\text{P}}$	20		40	s
$t_{25\text{P}}$	Total time from 25°C to peak temperature, $T_{\text{P}}$			480	s



## 11 Device and Documentation Support

### 11.1 Device Support

#### 11.1.1 Third-Party Products Disclaimer

TI'S PUBLICATION OF INFORMATION REGARDING THIRD-PARTY PRODUCTS OR SERVICES DOES NOT CONSTITUTE AN ENDORSEMENT REGARDING THE SUITABILITY OF SUCH PRODUCTS OR SERVICES OR A WARRANTY, REPRESENTATION OR ENDORSEMENT OF SUCH PRODUCTS OR SERVICES, EITHER ALONE OR IN COMBINATION WITH ANY TI PRODUCT OR SERVICE.

#### 11.2 Custom Design With WEBENCH® Tools

[Click here](#) to create a custom design using the TPS549D22 device with the WEBENCH® Power Designer.

1. Start by entering the input voltage ( $V_{IN}$ ), output voltage ( $V_{OUT}$ ), and output current ( $I_{OUT}$ ) requirements.
2. Optimize the design for key parameters such as efficiency, footprint, and cost using the optimizer dial.
3. Compare the generated design with other possible solutions from Texas Instruments.

The WEBENCH Power Designer provides a customized schematic along with a list of materials with real-time pricing and component availability.

In most cases, these actions are available:

- Run electrical simulations to see important waveforms and circuit performance
- Run thermal simulations to understand board thermal performance
- Export customized schematic and layout into popular CAD formats
- Print PDF reports for the design, and share the design with colleagues

Get more information about WEBENCH tools at [www.ti.com/WEBENCH](http://www.ti.com/WEBENCH).

#### 11.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

#### 11.4 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

**TI E2E™ Online Community** *TI's Engineer-to-Engineer (E2E) Community*. Created to foster collaboration among engineers. At [e2e.ti.com](http://e2e.ti.com), you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

**Design Support** *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

#### 11.5 Trademarks

D-CAP3, Eco-mode, NexFET, E2E are trademarks of Texas Instruments.

WEBENCH is a registered trademark of Texas Instruments.

PMBus is a trademark of SMIF, Inc..

All other trademarks are the property of their respective owners.

#### 11.6 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

## 11.7 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

## 12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

## 12.1 Package Option Addendum

### 12.1.1 Packaging Information

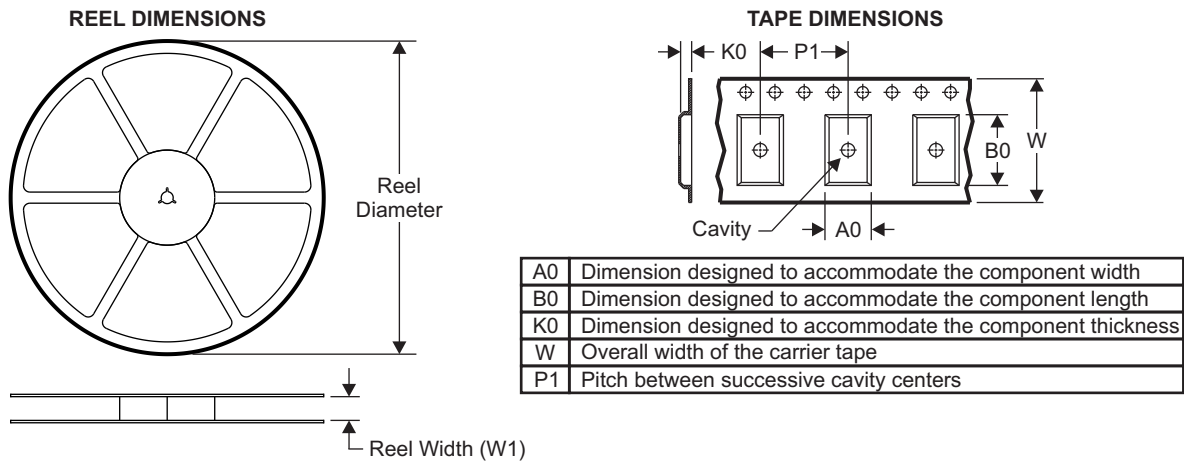
Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/Ball Finish <sup>(3)</sup>	MSL Peak Temp <sup>(4)</sup>	Op Temp (°C)	Device Marking <sup>(5)(6)</sup>
TPS549D22RVFR	ACTIVE	LQFN-CLIP	RVF	40	2500	Pb-Free (RoHS Exempt)	CU NIPDAU	Level-2-260C-1 YEAR	–40 to 125	TPS549D22
TPS549D22RVFT	ACTIVE	LQFN-CLIP	RVF	40	250	Pb-Free (RoHS Exempt)	CU NIPDAU	Level-2-260C-1 YEAR	–40 to 125	TPS549D22

- (1) The marketing status values are defined as follows:  
**ACTIVE:** Product device recommended for new designs.  
**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.  
**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.  
**PRE\_PROD** Unannounced device, not in production, not available for mass market, nor on the web, samples not available.  
**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.  
**OBSOLETE:** TI has discontinued the production of the device.
- (2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.  
**TBD:** The Pb-Free/Green conversion plan has not been defined.  
**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.  
**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.  
**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)
- (3) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.
- (4) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (5) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device
- (6) Multiple Device markings will be inside parentheses. Only on Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

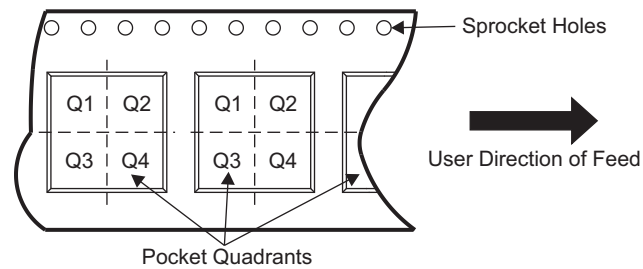
**Important Information and Disclaimer:** The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

## 12.1.2 Tape and Reel Information



### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



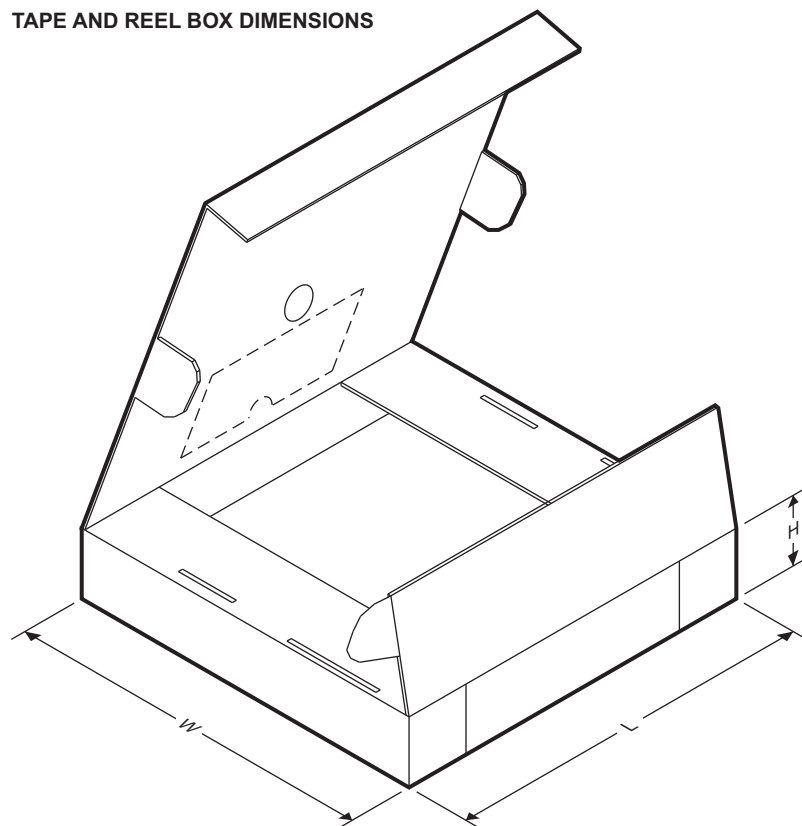
Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS549D22RVFR	LQFN-CLIP	RVF	40	2500	330.0	16.4	5.35	7.35	1.7	8.0	16.0	Q3
TPS549D22RVFT	LQFN-CLIP	RVF	40	250	178.0	16.4	5.35	7.35	1.7	8.0	16.0	Q3

## TPS549D22

SLUSCI9A –AUGUST 2016–REVISED SEPTEMBER 2017

[www.ti.com](http://www.ti.com)

### TAPE AND REEL BOX DIMENSIONS



Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS549D22RVFR	LQFN-CLIP	RVF	40	2500	367.0	367.0	38.0
TPS549D22RVFT	LQFN-CLIP	RVF	40	250	210.0	185.0	35.0

## PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package   Pins	Package qty   Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
<a href="#">TPS549D22RVFR</a>	Active	Production	LQFN-CLIP (RVF)   40	2500   LARGE T&R	ROHS Exempt	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	TPS549D22
<a href="#">TPS549D22RVFT</a>	Active	Production	LQFN-CLIP (RVF)   40	250   SMALL T&R	ROHS Exempt	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	TPS549D22
TPS549D22RVFTG4	Active	Production	LQFN-CLIP (RVF)   40	250   SMALL T&R	ROHS Exempt	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	TPS549D22

<sup>(1)</sup> **Status:** For more details on status, see our [product life cycle](#).

<sup>(2)</sup> **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

<sup>(4)</sup> **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

**Important Information and Disclaimer:** The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

## TAPE AND REEL INFORMATION



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS549D22RVFR	LQFN-CLIP	RVF	40	2500	330.0	16.4	5.35	7.35	1.7	8.0	16.0	Q1
TPS549D22RVFT	LQFN-CLIP	RVF	40	250	180.0	16.4	5.35	7.35	1.7	8.0	16.0	Q1
TPS549D22RVFTG4	LQFN-CLIP	RVF	40	250	180.0	16.4	5.35	7.35	1.7	8.0	16.0	Q1

## TAPE AND REEL BOX DIMENSIONS



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS549D22RVFR	LQFN-CLIP	RVF	40	2500	367.0	367.0	38.0
TPS549D22RVFT	LQFN-CLIP	RVF	40	250	210.0	185.0	35.0
TPS549D22RVFTG4	LQFN-CLIP	RVF	40	250	210.0	185.0	35.0

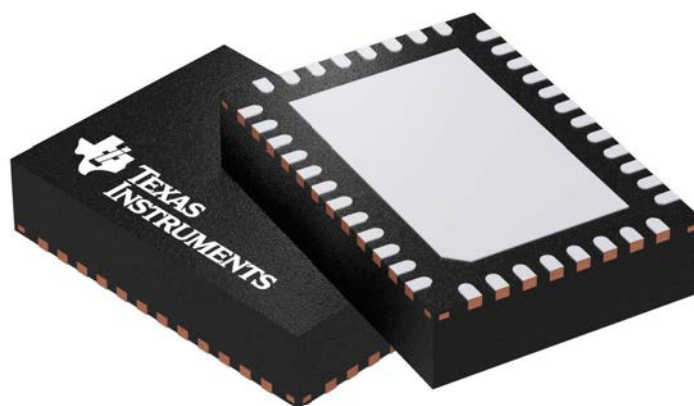


## GENERIC PACKAGE VIEW

**RVF 40**

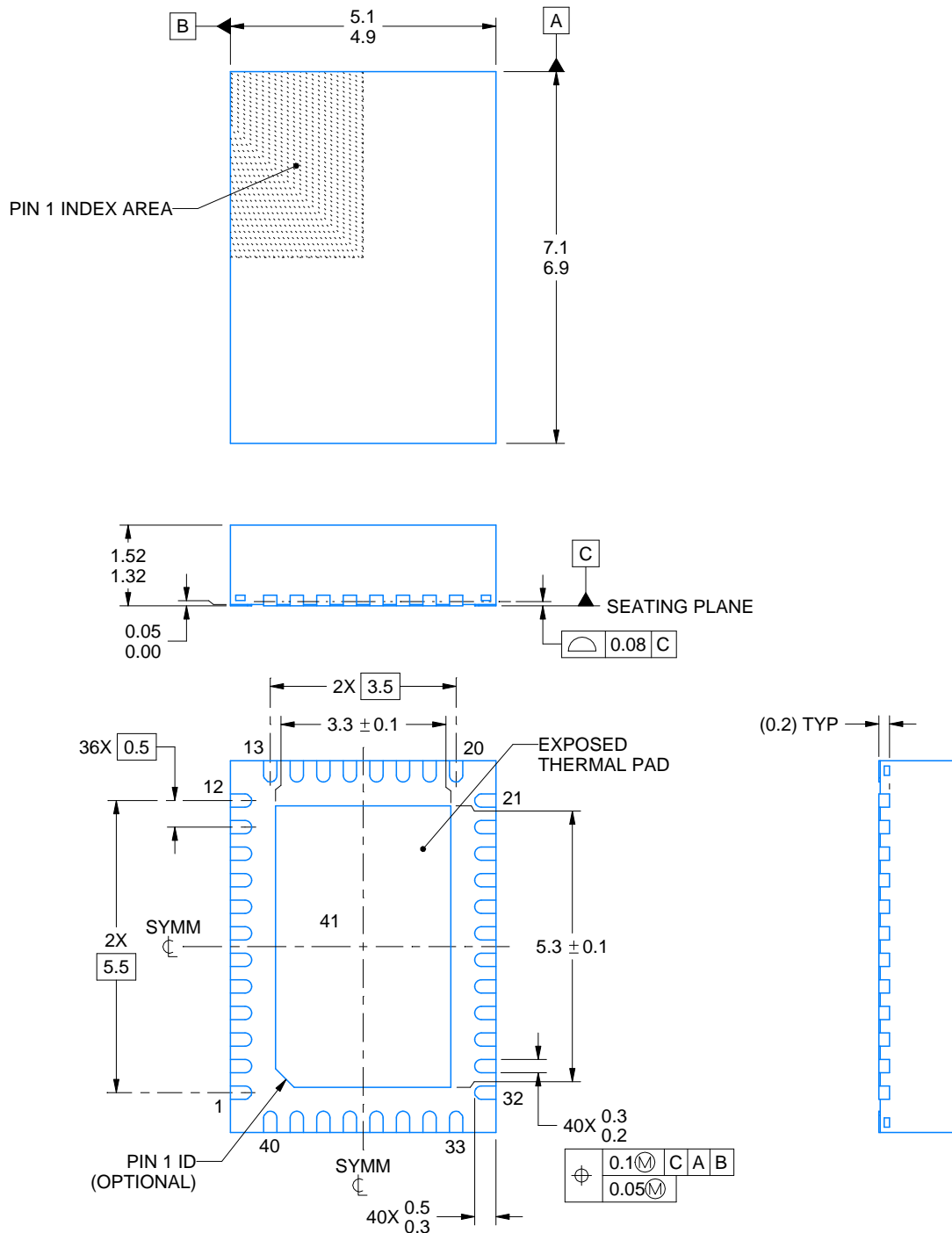
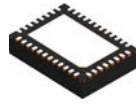
**LQFN-CLIP - 1.52 mm max height**

PLASTIC QUAD FLATPACK - NO LEAD



Images above are just a representation of the package family, actual package may vary.  
Refer to the product data sheet for package details.

4211383/D



4222989/B 10/2017

## NOTES:

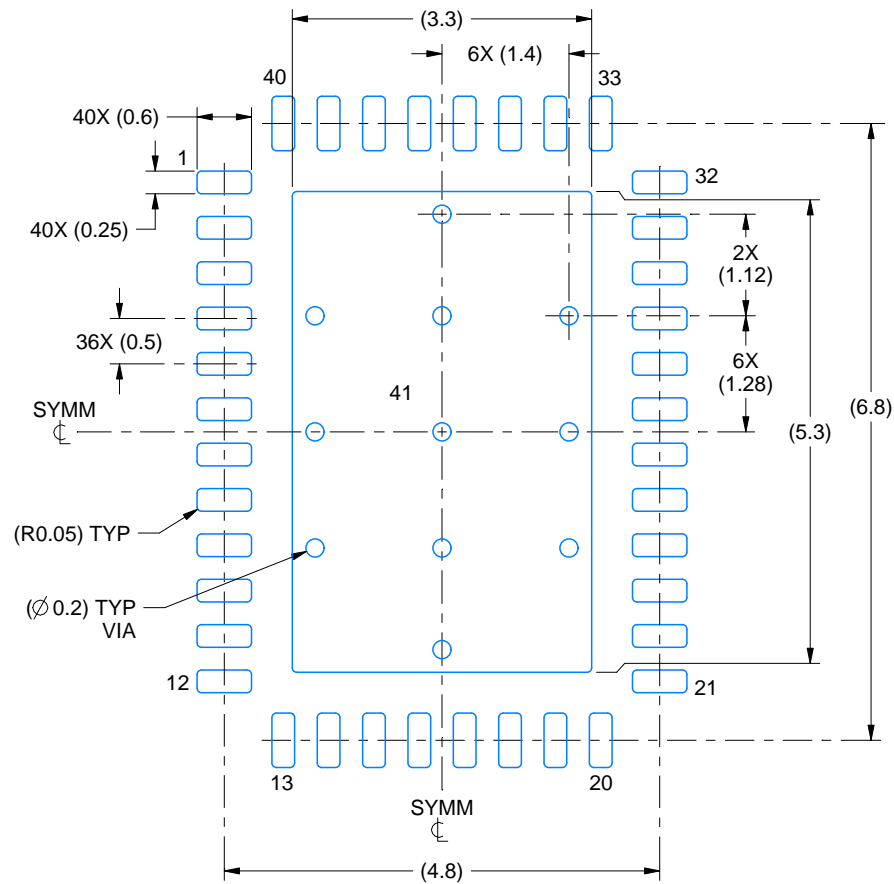
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.
4. Reference JEDEC registration MO-220.

# EXAMPLE BOARD LAYOUT

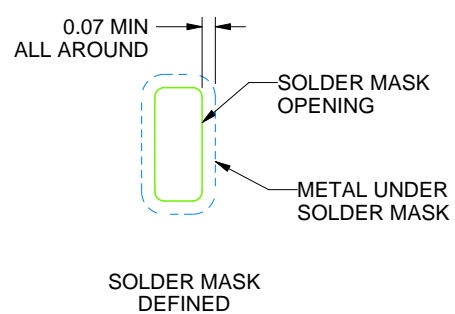
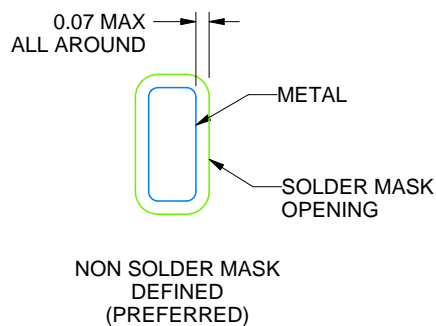
RVF0040A

LQFN-CLIP - 1.52 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



LAND PATTERN EXAMPLE  
SCALE:12X



SOLDER MASK DETAILS

4222989/B 10/2017

NOTES: (continued)

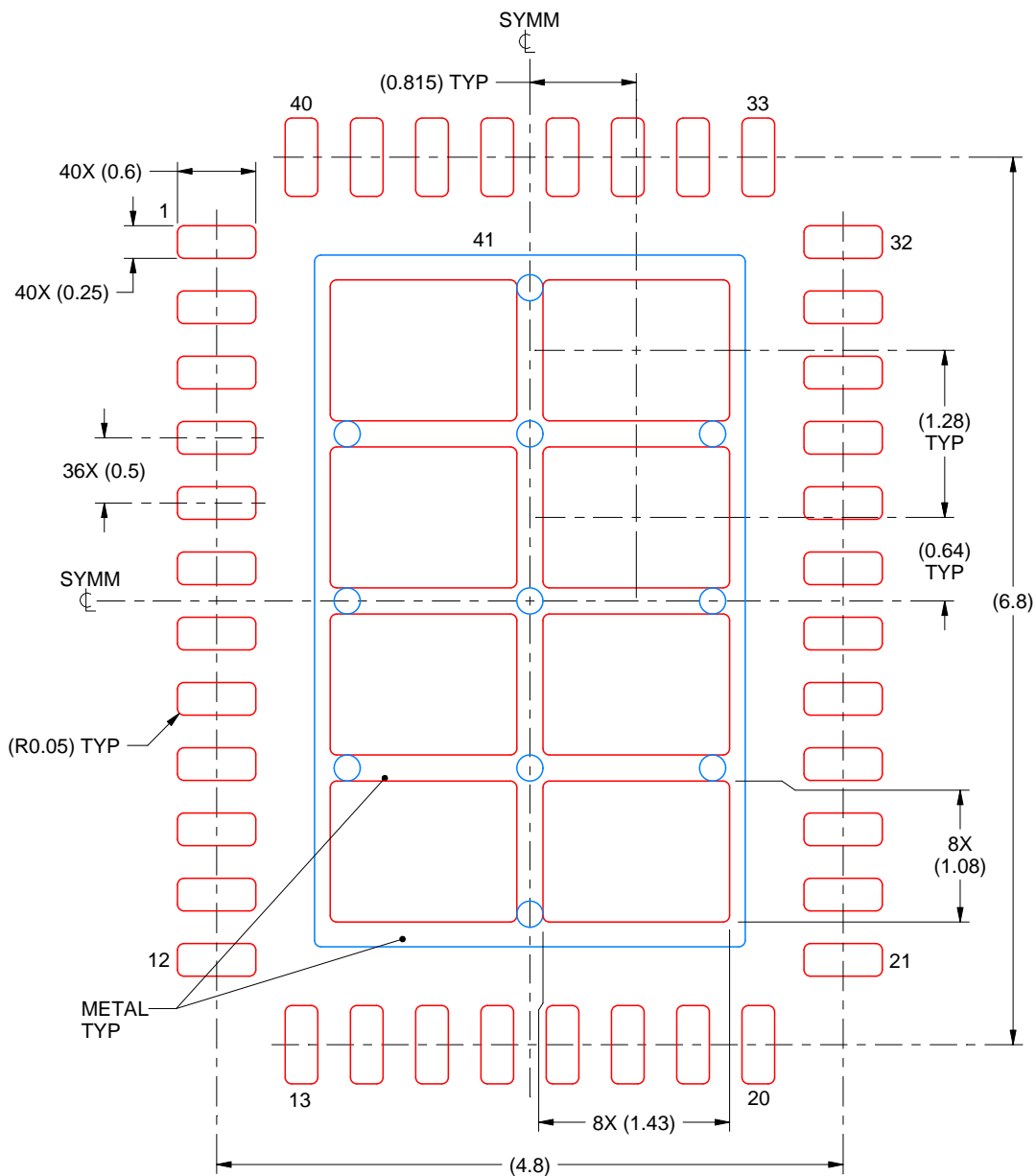
5. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 ([www.ti.com/lit/sluea271](http://www.ti.com/lit/sluea271)).

# EXAMPLE STENCIL DESIGN

**RVF0040A**

**LQFN-CLIP - 1.52 mm max height**

PLASTIC QUAD FLATPACK - NO LEAD



**SOLDER PASTE EXAMPLE**  
 BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD  
 71% PRINTED SOLDER COVERAGE BY AREA  
 SCALE:18X

4222989/B 10/2017

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

## IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you fully indemnify TI and its representatives against any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to [TI's Terms of Sale](#), [TI's General Quality Guidelines](#), or other applicable terms available either on [ti.com](https://www.ti.com) or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products. Unless TI explicitly designates a product as custom or customer-specified, TI products are standard, catalog, general purpose devices.

TI objects to and rejects any additional or different terms you may propose.

Copyright © 2026, Texas Instruments Incorporated

Last updated 10/2025